TEXAS INSTRUMENTS

AFE4404

SBAS689D – JUNE 2015 – REVISED DECEMBER 2016

AFE4404 Ultra-Small, Integrated AFE for Wearable, Optical, Heart-Rate Monitoring and Bio-Sensing

1 Features

- Transmitter:
  - Supports Common Anode LED Configuration
  - Dynamic Range: 100 dB
  - 6-Bit Programmable LED Current to 50 mA (Extendable to 100 mA)
  - Programmable LED On-Time
  - Simultaneous Support of 3 LEDs for Optimized SpO2, HRM, or Multi-Wavelength HRM
- Receiver:
  - 24-Bit Representation of the Current Input from a Photodiode in Twos Complement Format
  - Individual DC Offset Subtraction DAC at TIA Input for Each LED and Ambient Phase
  - Digital Ambient Subtraction at ADC Output
  - Programmable Transimpedance Gain: 10 kΩ to 2 MΩ
  - Dynamic Range: 100 dB
  - Average Current Less Than 200 μA for PPG Signal Acquisition
- Pulse Frequency: 10 SPS to 1000 SPS
- Flexible Pulse Sequencing and Timing Control
- Flexible Clock Options:
  - External Clocking: 4-MHz to 60-MHz Input Clock
  - Internal Clocking: 4-MHz Oscillator
- I²C Interface
- Operating Temperature Range: –20°C to 70°C
- 2.6-mm × 1.6-mm DSBGA Package, 0.5-mm Pitch
- Supplies: Rx: 2 V to 3.6 V, Tx: 3 V to 5.25 V, IO: 1.8 V to 3.6 V

2 Applications

- Optical Heart-Rate Monitoring (HRM)
- Heart-Rate Variability (HRV)
- Pulse Oximetry (SpO2 Measurement)
- VO2 Max
- Calorie Expenditure

3 Description

The AFE4404 is an analog front-end (AFE) for optical bio-sensing applications, such as heart-rate monitoring (HRM) and saturation of peripheral capillary oxygen (SpO2). The device supports three switching light-emitting diodes (LEDs) and a single photodiode. The current from the photodiode is converted into voltage by the transimpedance amplifier (TIA) and digitized using an analog-to-digital converter (ADC). The ADC code can be read out using an I²C interface. The AFE also has a fully-integrated LED driver with a 6-bit current control. The device has a high dynamic range transmit and receive circuitry that helps with the sensing of very small signal levels.

Device Information[1]

PART NUMBER	PACKAGE	BODY SIZE (NOM)
AFE4404	DSBGA (15)	2.60 mm × 1.60 mm[2]

(1) For all available packages, see the orderable addendum at the end of the datasheet.

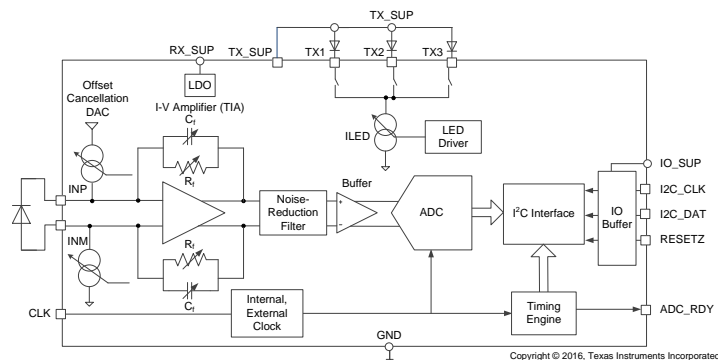(2) Refers to dimensions D × E in Figure 99.

Simplified Block Diagram

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4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision C (May 2016) to Revision D   **Page**

- Changed last sub-bullet of *Receiver* Features bullet 1
- Changed test conditions of *dynamic power-down mode* rows in *Current Consumption* subsection of *Electrical Characteristics* table 8

Changes from Revision B (October 2015) to Revision C   **Page**

- Changed specifications of t_1 and t_4 rows in Table 7 to improve rejection of ambient light................................ 24
- Changed *Description* column in Table 10 26
- Changed Table 11 27
- Changed Table 12 28
- Added *Reducing Sensitivity to Ambient Light Modulation* section.. 70

Changes from Revision A (August 2015) to Revision B   **Page**

- Changed TX_SUP pin number to E3 in *Pin Functions* table 5
- Added Figure 9 10
- Added *Decimation Mode* section 32
- Added rows 3Dh, 3Fh, and 40h to Table 16 35
- Added Register 3Dh description to *Register Map* section.. 66
- Added Register 3Fh and Register 40h descriptions to *Register Map* section.. 67
- Added *System-Level ESD Considerations* section 69
- Added input-referred current paragraph associated to Figure 9 in *Application Curves* section............................. 72

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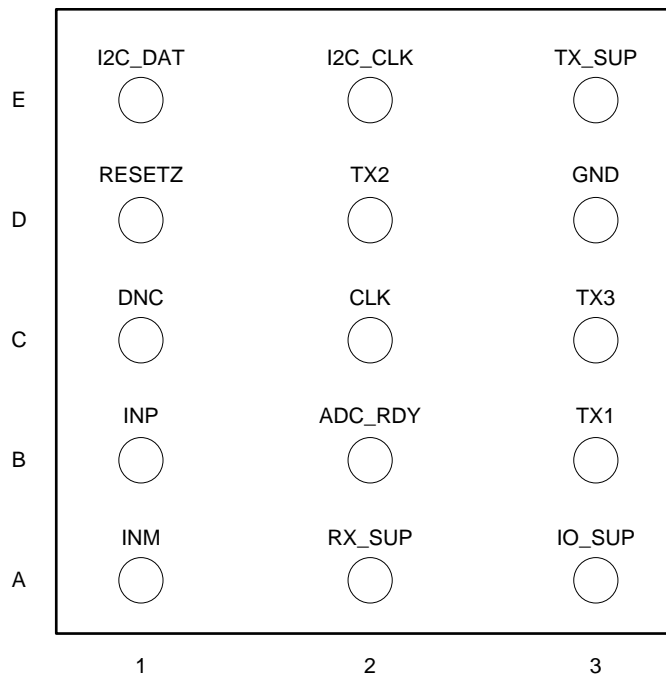
5 Device Comparison Table

PRODUCT	PACKAGE-LEAD	LED DRIVE CONFIGURATION	LED DRIVE CURRENT (mA, Max)	OPERATING TEMPERATURE RANGE	OPTIMIZED APPLICATION
AFE4400	VQFN-40	H-bridge, common anode	50	0°C to 70°C	Finger-clip pulse oximeters
AFE4490	VQFN-40	H-bridge, common anode	200	–40°C to 85°C	Clinical-grade pulse oximeters
AFE4403	DSBGA-36	H-bridge, common anode	100	–20°C to 70°C	Clinical pulse oximeter patches, wearables
AFE4404	DSBGA-15	Common anode	50[(1)]	–20°C to 70°C	Wearable optical bio-sensing

(1) Mode that doubles the range to 100 mA with additional restrictions.

6 Pin Configuration and Functions

YZP Package
15-Ball DSBGA
Bottom View

Product Folder Links: *AFE4404*

Pin Functions

PIN		I/O	DESCRIPTION
NAME	NO.		
ADC_RDY	B2	Digital	ADC ready interrupt signal (output)
CLK	C2	Digital	Clock input or output, selectable based on register. Default is input (external clock mode). Can be set via a register to output the clock when the oscillator is enabled. [1] [2]
DNC	C1		Do not connect (leave floating)
GND	D3	Ground	Common ground for transmitter and receiver
I2C_CLK	E2	Digital	I2C clock input, external pullup resistor to IO_SUP (for example, 10 kΩ)
I2C_DAT	E1	Digital	I2C data, external pullup resistor to IO_SUP (for example, 10 kΩ)
INM	A1	Analog	Connect only to anode of photodiode[3]
INP	B1	Analog	Connect only to cathode of photodiode[3]
IO_SUP	A3	Supply	Separate supply for digital I/O. Must be less than or equal to RX_SUP. Can be tied to RX_SUP.
RESETZ	D1	Digital	RESETZ or PWDN: function based on (active low) duration of RESETZ pulse[4]. A 25-µs to 50-µs duration = RESETZ active. A > 200-µs duration = PWDN active.
RX_SUP	A2	Supply	Receiver supply; 1-µF decapacitor to GND
TX1	B3	Analog	Transmit output, LED1
TX2	D2	Analog	Transmit output, LED2
TX3	C3	Analog	Transmit output, LED3
TX_SUP	E3	Supply	Transmitter supply; 1-µF decapacitor to GND

(1) Depending on whether external clock mode or internal oscillator mode is used, extra series or shunt resistors are recommended on the CLK pin. For more details, see the *Typical Application* section.
(2) In both hardware power-down (PWDN) and software power-down (PDNAFE) modes, the CLK pin is driven by the AFE to 0 V. Therefore, if operating in external clock mode, take care to shut off the external clock to the AFE when in these power-down modes.
(3) Maintain the indicated polarity of photodiode connections to the AFE input pins.
(4) A RESET pulse must be applied after power-up to ensure that the registers are all reset to their default values.

7 Specifications

7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)[1]

		MIN	MAX	UNIT
Supply voltage range	RX_SUP to GND	−0.3	4	V
	IO_SUP to GND	−0.3	4	
	RX_SUP-IO_SUP	−0.3		
	TX_SUP to GND	−0.3	6	
Voltage applied to analog inputs		Max [−0.3, (GND − 0.3)]	Min [4, (RX_SUP + 0.3)]	V
Voltage applied to digital inputs		Max [−0.3, (GND − 0.3)]	Min [4, (IO_SUP + 0.3)]	V
Maximum duty cycle (cumulative): sum of all LED phase durations as a function of the total period	50-mA LED current mode (ILED_2X = 0)		10%	
	100-mA LED current mode (ILED_2X = 1)		3%	
Storage temperature, T_{stg}		−60	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

7.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001[1]	±1000	V
		Charged device model (CDM), per JEDEC specification JESD22-C101[2]	±250	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

7.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
RX_SUP	Receiver supply		2	3.6	V
IO_SUP	Input/output supply		1.7	Min (3.6, RX_SUP)	V
TX_SUP	Transmitter supply	50-mA LED current mode (ILED_2X = 0)	3.0 or (0.5 + V_{LED})[1], whichever is greater	5.25	V
		100-mA LED current mode (ILED_2X = 1)	3.0 or (1.0 + V_{LED})[1], whichever is greater	5.25	
	Digital inputs		0	IO_SUP	V
	Analog inputs		0	RX_SUP	V
	Operating temperature range		−20	70	°C

(1) V_{LED} refers to the maximum voltage drop across the external LED (at maximum LED current). This value is usually governed by the forward drop voltage (V_{FB}) of the LED.

7.4 Thermal Information

	THERMAL METRIC[1]	AFE4404 YZP (DSBGA) 15 BALLS	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance	67.5	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	0.5	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	12.9	°C/W
ψ_{JT}	Junction-to-top characterization parameter	0.2	°C/W
ψ_{JB}	Junction-to-board characterization parameter	12.9	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report.

7.5 Electrical Characteristics

Minimum and maximum specifications are at T_A = −20°C to 70°C, typical specifications are at 25°C. TX_SUP = 4 V, RX_SUP = IO_SUP = 3 V, 100-Hz PRF, 8-MHz external clock (with CLKDIV_EXTMODE set to divide-by-2), detector C_{IN} = 50 pF, and CLKDIV_PRF set to 1, unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
PULSE REPETITION FREQUENCY						
PRF[1]	Pulse repetition frequency		10[2]		1000	SPS
RECEIVER						
	Offset cancellation DAC current range			−7 to 7		µA
	Offset cancellation DAC current step			0.47		µA
	TIA gain setting			10k to 2M		Ω
	C_f setting			2.5 to 25		pF
	Switched RC filter bandwidth			2.5[3]		kHz
	ADC averages		1		16	
	Detector capacitance	Differential capacitance between INP, INN	10		200	pF
TRANSMITTER						
	LED current range	ILED_2X = 0		0 to 50		mA
		ILED_2X = 1		0 to 100		
	LED current resolution			6		Bits
CLOCKING (Internal Oscillator)						
	Frequency			4		MHz
	Accuracy	Room temperature		±1%		
	Frequency drift with temperature	Full temperature range		±0.5%		
	Jitter (RMS)			100		ps
	Output clock high level			IO_SUP		V
	Output clock low level			0		V
	Output clock rise and fall times	10% to 90%, 15-pF load capacitance on CLK pin		< 30		ns
CLOCKING (External Clock)						
	Frequency range[4]		4		60	MHz
	Input clock high level			IO_SUP		V
	Input clock low level			0		V
	Input capacitance of CLK pin	Capacitance to ground		< 4		pF
I²C INTERFACE						
	Maximum clock speed			400		kHz
	I²C slave address			58		Hex
PERFORMANCE						
	Receiver SNR	SNR over a 20-Hz bandwidth for a 500-kΩ gain setting, 50% FS output, 2% LED and sampling pulse duration, ADC averages set to 16		100		dBFS[5]
	Transmitter SNR	SNR over a 20-Hz bandwidth for a 50-mA LED current setting		100		dBFS[5]

(1) PRF refers to the rate at which samples from each of the four phases are output from the AFE.
(2) To extend the lower range of PRF down to 10 Hz, program the CLKDIV_PRF setting.
(3) The effective bandwidth of the switched RC filter scales as a function of the sampling duty cycle. For example, at 2% sampling width duty cycle, the effective bandwidth of the switched RC filter is approximately 50 Hz.
(4) With appropriate setting of the clock divider ratio (CLKDIV_EXTMODE).
(5) dBFS refers to a full-scale voltage of 2 V.

Electrical Characteristics (continued)

Minimum and maximum specifications are at T_A = –20°C to 70°C, typical specifications are at 25°C. TX_SUP = 4 V, RX_SUP = IO_SUP = 3 V, 100-Hz PRF, 8-MHz external clock (with CLKDIV_EXTMODE set to divide-by-2), detector C_{IN} = 50 pF, and CLKDIV_PRF set to 1, unless otherwise noted.

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
CURRENT CONSUMPTION						
RX_SUP current		Normal operation, in dynamic power-down mode[6]		300		µA
		Always ON receiver, external clock mode		620		
		Always ON receiver, internal oscillator mode		670		
		Hardware power-down (PWDN) mode[7]		3		
		Software power-down (PDNAFE) mode[7]		35		
IO_SUP current		Normal operation, in dynamic power-down mode[6]		20		µA
		Always ON receiver, external clock mode		20		
		Always ON receiver, internal oscillator mode		5		
		Hardware power-down (PWDN) mode[7]		3		
		Software power-down (PDNAFE) mode[7]		5		
TX_SUP current		Normal operation, in dynamic power-down mode[6][8]		5		µA
		Always ON receiver, external clock mode[8]		25		
		Always ON receiver, internal oscillator mode[8]		25		
		Hardware power-down (PWDN) mode[7][8]		2		
		Software power-down (PDNAFE) mode[7][8]		2		
TRANSIENT RECOVERY						
t_{ACTIVE}	Recovery from PWDN mode	Time for signal chain to be functional[9]		10		ms
$t_{CHANNEL}$	Recovery from any event causing a change in signal characteristics	PRF = 100 Hz, sampling duty cycle (each phase) of 2%[10]		200		ms
DIGITAL INPUTS						
V_{IH}	High-level input voltage		0.9 × IO_SUP	IO_SUP		V
V_{IL}	Low-level input voltage		0		0.1 × IO_SUP	V
DIGITAL OUTPUTS						
V_{OH}	High-level output voltage			IO_SUP		V
V_{OL}	Low-level output voltage			0		V

(6) In dynamic power-down mode for 90% and active mode for 10% of the period.
(7) External clock mode with the external clock switched off.
(8) LED currents set to 0 mA.
(9) For full performance to be restored, a longer time as governed by $t_{CHANNEL}$ can be applicable.
(10) $t_{CHANNEL}$ scales inversely with the sampling duty cycle.

7.6 Timing Requirements

		MIN	TYP	MAX	UNIT
t_{I2C_RISE}	I²C data rise time with a 10-kΩ pullup resistor with a 20-pF load from I²C data to GND		1200		ns
t_{I2C_FALL}	I²C data fall time (when the data line is pulled down by the AFE) with a 20-pF load from I²C data to GND		28		ns
$t_{ADC\_RDY\_RISE}$	ADC_RDY rise time (10% to 90%) with a 15-pF capacitive load to ground		21		ns
$t_{ADC\_RDY\_FALL}$	ADC_RDY fall time (90% to 10%) with a 15-pF capacitive load to ground		21		ns

Product Folder Links: *AFE4404*

7.7 Typical Characteristics

At 25°C, TX_SUP = 4 V, RX_SUP = IO_SUP = 3.3 V, 100-Hz PRF, 25% duty cycle, R_f = 500 kΩ, C_f is adjusted to keep the TIA time constant at 1/10th of the sampling duration, 8-MHz external clock (with CLKDIV_EXTMODE set to divide-by-2), CLKDIV_PRF = 1, detector C_{IN} = 50 pF, ADC averaging = max allowed, SNR (dBFS) = noise referred to full-scale range of 2 V, noise integrated from 1 Hz to Nyquist (= PRF / 2), and values assigned to CLKDIV_EXTMODE and CLK_DIV_PRF parameters correspond to division ratios controlled by these modes, unless otherwise specified.
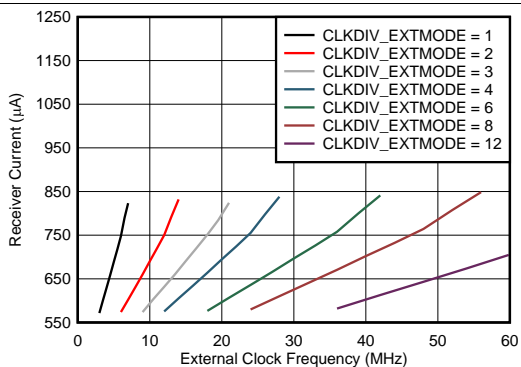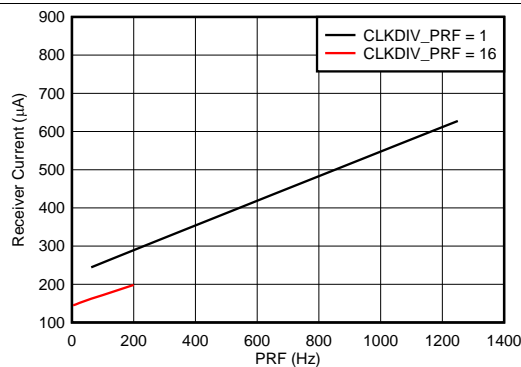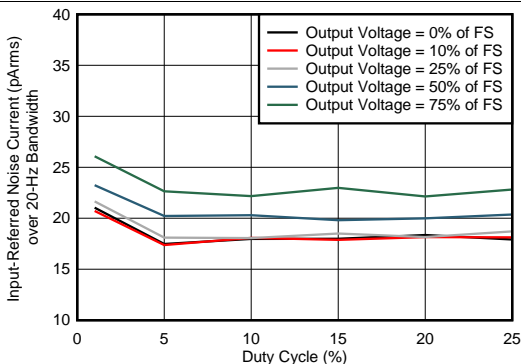

Figure 1. Receiver Current vs External Clock Frequency

Active window = 500 μs, LED pulse = 100 μs,
all four DYNAMIC bits set to 1

**Figure 2. Receiver Current vs PRF in
Dynamic Power-Down Mode**

Duty cycle (x-axis) refers to the sampling duration expressed as a percentage of the pulse repetition period.

**Figure 3. Input-Referred Noise Current in 20-Hz Bandwidth
vs Duty Cycle for Different Output Levels
(As a Percentage of Full-Scale)**
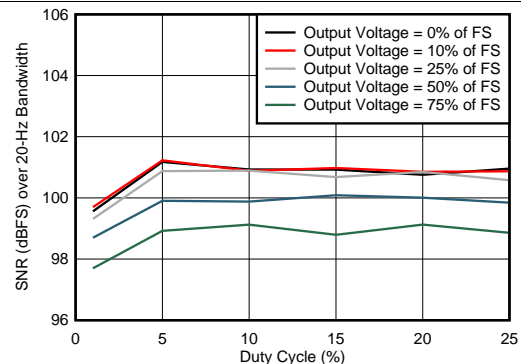
Duty cycle (x-axis) refers to the sampling duration expressed as a percentage of the pulse repetition period.

**Figure 4. Signal-to-Noise Ratio in 20-Hz Bandwidth vs Duty
Cycle for Different Output Levels
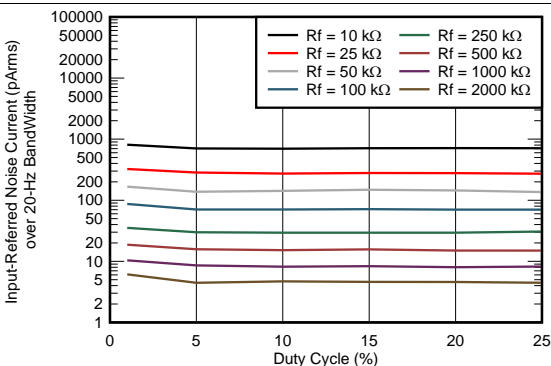(As a Percentage of Full-Scale)**

**Figure 5. Receiver Input-Referred Noise Current in 20-Hz
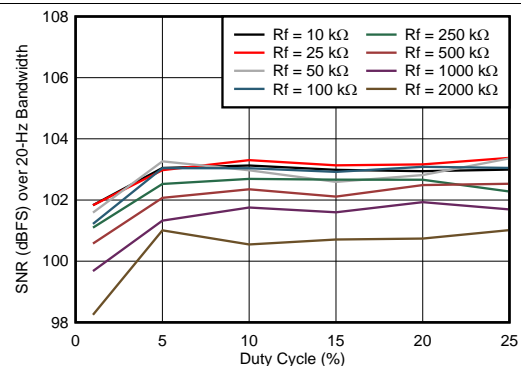BW vs Duty Cycle (Different TIA Gain Settings)**

**Figure 6. Receiver SNR in 20-Hz BW vs Duty Cycle
(Different TIA Gain Settings)**

Product Folder Links: *AFE4404*

Typical Characteristics (continued)

At 25°C, TX_SUP = 4 V, RX_SUP = IO_SUP = 3.3 V, 100-Hz PRF, 25% duty cycle, R_f = 500 kΩ, C_f is adjusted to keep the TIA time constant at 1/10th of the sampling duration, 8-MHz external clock (with CLKDIV_EXTMODE set to divide-by-2), CLKDIV_PRF = 1, detector C_{IN} = 50 pF, ADC averaging = max allowed, SNR (dBFS) = noise referred to full-scale range of 2 V, noise integrated from 1 Hz to Nyquist (= PRF / 2), and values assigned to CLKDIV_EXTMODE and CLK_DIV_PRF parameters correspond to division ratios controlled by these modes, unless otherwise specified.

Figure 7. Receiver Input-Referred Noise Current over Nyquist Bandwidth vs Duty Cycle (Different ADC Averaging)
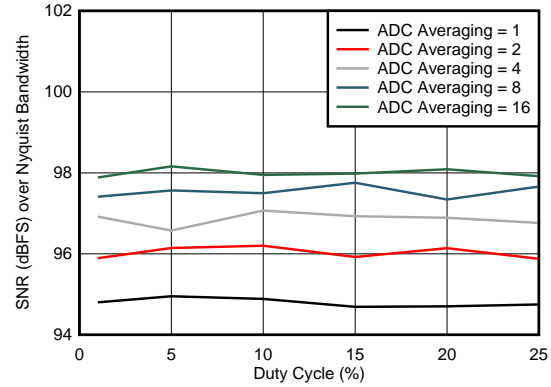
Figure 8. Receiver Signal-to-Noise Ratio over Nyquist Bandwidth vs Duty Cycle (Different ADC Averaging)
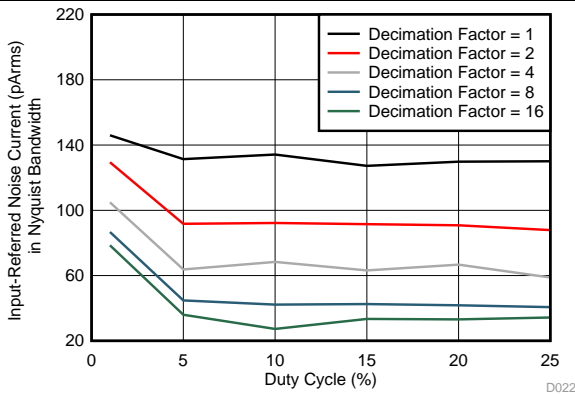
Figure 9. Input-Referred Noise Current in Nyquist Bandwidth vs Duty Cycle (Different Decimation Factor)
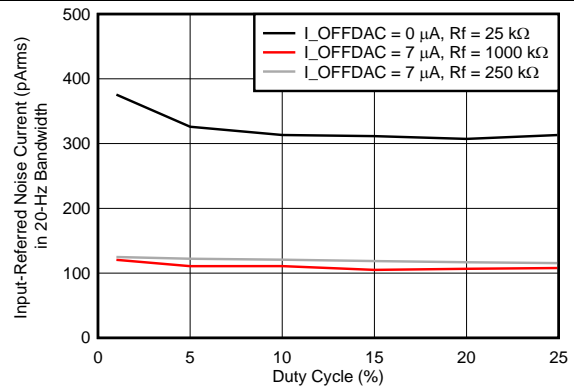
Figure 10. Receiver Input-Referred Noise in 20-Hz Bandwidth vs Duty Cycle (Different Offset Cancellation DAC Currents)
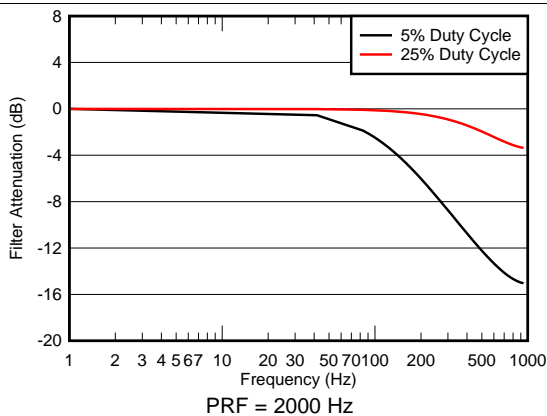
Figure 11. Response of the Switched-RC Filter at the AFE Output
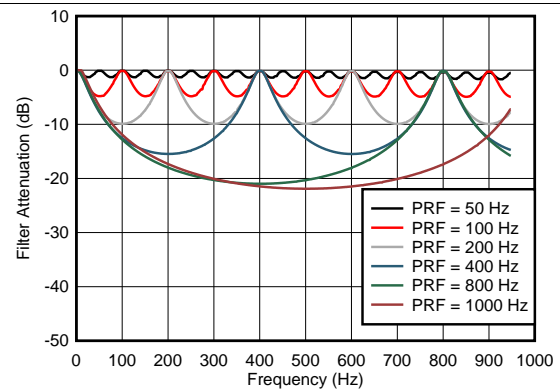
Figure 12. Filter Response for Multiple PRFs at 1% Duty Cycle

Product Folder Links: *AFE4404*

Typical Characteristics (continued)

At 25°C, TX_SUP = 4 V, RX_SUP = IO_SUP = 3.3 V, 100-Hz PRF, 25% duty cycle, R_f = 500 kΩ, C_f is adjusted to keep the TIA time constant at 1/10th of the sampling duration, 8-MHz external clock (with CLKDIV_EXTMODE set to divide-by-2), CLKDIV_PRF = 1, detector C_{IN} = 50 pF, ADC averaging = max allowed, SNR (dBFS) = noise referred to full-scale range of 2 V, noise integrated from 1 Hz to Nyquist (= PRF / 2), and values assigned to CLKDIV_EXTMODE and CLK_DIV_PRF parameters correspond to division ratios controlled by these modes, unless otherwise specified.
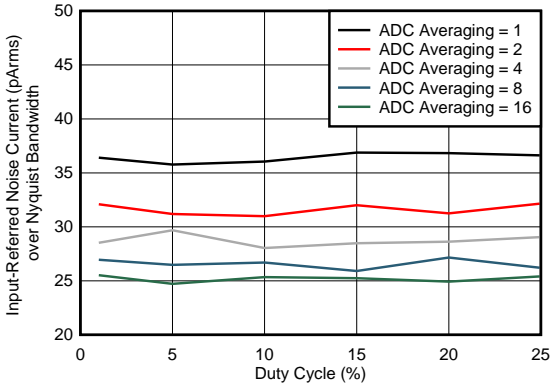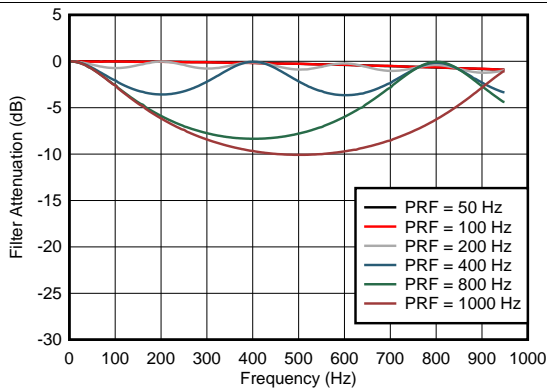

Figure 13. Filter Response for Multiple PRFs at 5% Duty Cycle
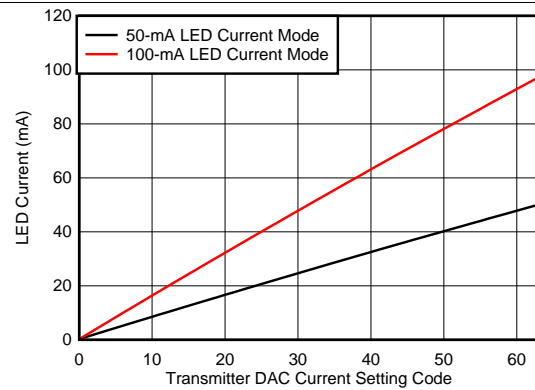
Figure 14. Transmitter Current Linearity
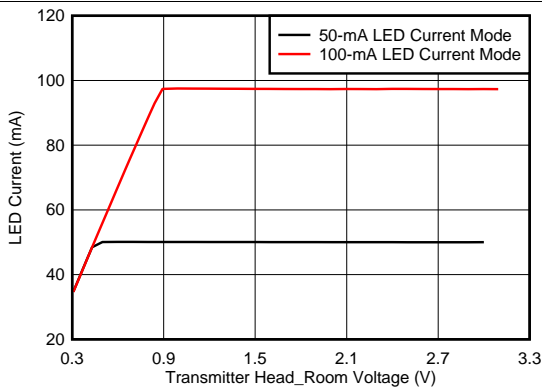
Figure 15. LED Current vs Transmitter Headroom Voltage
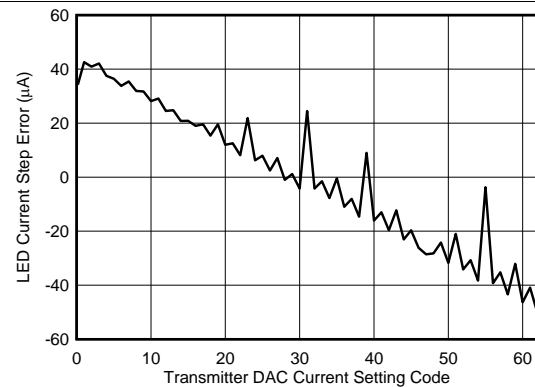
Figure 16. Transmitter DAC Current Step Error in 50-mA Mode
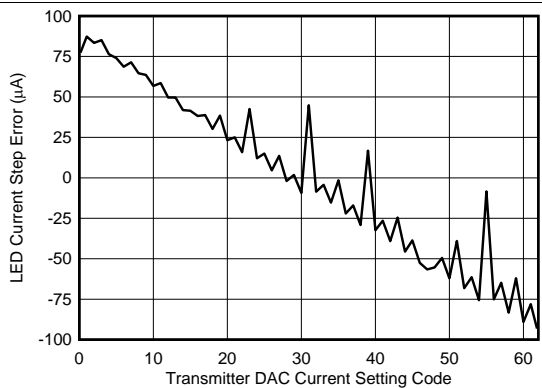
Figure 17. Transmitter DAC Current Step Error in 100-mA Mode
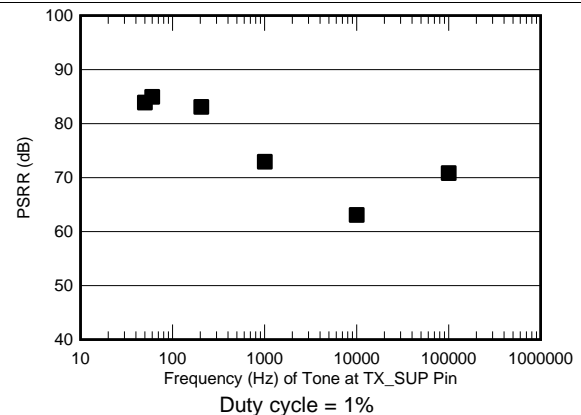
Figure 18. PSRR vs Tone Frequency at TX_SUP

Product Folder Links: *AFE4404*

Typical Characteristics (continued)

At 25°C, TX_SUP = 4 V, RX_SUP = IO_SUP = 3.3 V, 100-Hz PRF, 25% duty cycle, R_f = 500 kΩ, C_f is adjusted to keep the TIA time constant at 1/10th of the sampling duration, 8-MHz external clock (with CLKDIV_EXTMODE set to divide-by-2), CLKDIV_PRF = 1, detector C_{IN} = 50 pF, ADC averaging = max allowed, SNR (dBFS) = noise referred to full-scale range of 2 V, noise integrated from 1 Hz to Nyquist (= PRF / 2), and values assigned to CLKDIV_EXTMODE and CLK_DIV_PRF parameters correspond to division ratios controlled by these modes, unless otherwise specified.
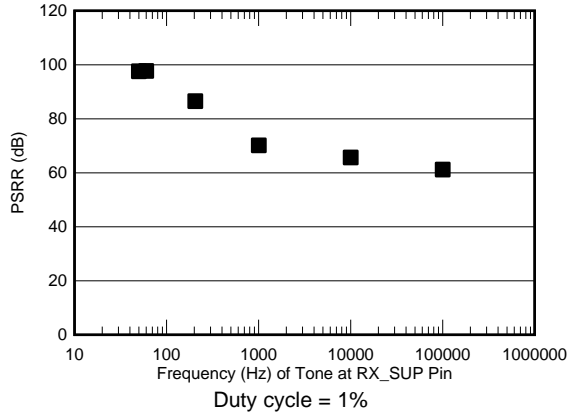
Duty cycle = 1%

Figure 19. PSRR vs Tone Frequency at RX_SUP

PRF = 200 Hz, NUMAV = 0
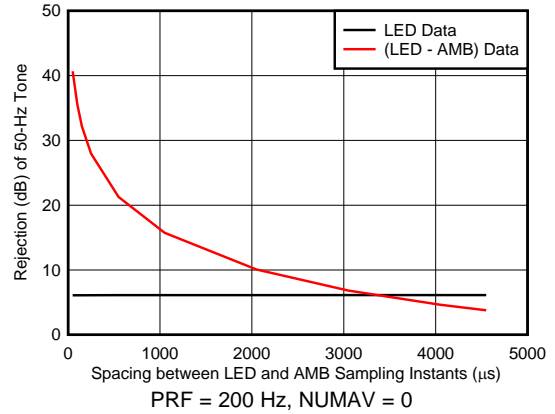
Figure 20. Rejection of a 50-Hz Differential Tone Across Spacing Between LED and Ambient Phases
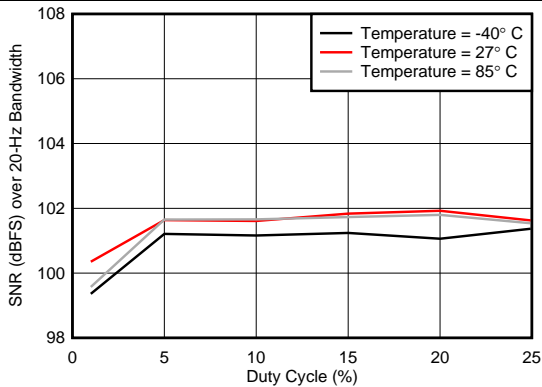
Figure 21. Receiver SNR in a 20-Hz Bandwidth vs Duty Cycle Across Different Temperatures
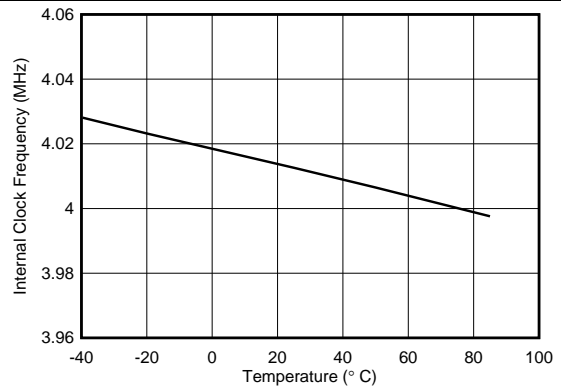
Figure 22. Internal Oscillator Frequency vs Temperature on a Typical Unit

Product Folder Links: *AFE4404*

8 Detailed Description

8.1 Overview

The AFE has an integrated transmitter and receiver for optical heart-rate monitoring and pulse oximetry applications. The system is characterized by a parameter termed the *pulse repetition frequency (PRF)* that determines the repetition periodicity of a sequence of operations. Every cycle of a PRF results in four 24-bit digital samples at the output of the AFE, each of which is stored in a separate register.

8.2 Functional Block Diagram

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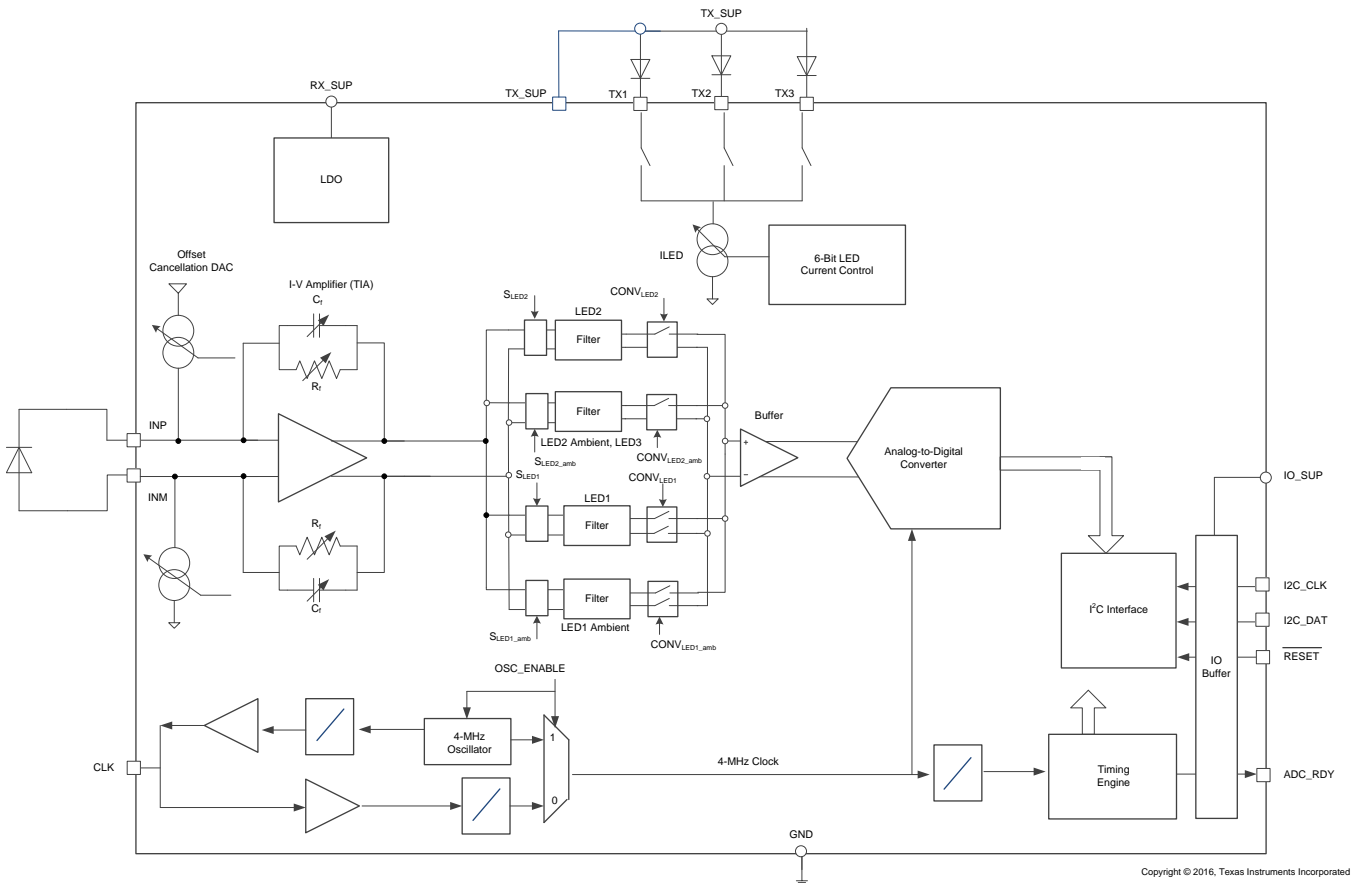
8.3 Feature Description

8.3.1 TIA and Switched RC Filter

The receiver input pins (INP, INM) are meant to be connected differentially to a photodiode. The signal current from the photodiode is converted to a differential voltage using a transimpedance amplifier (TIA). The TIA gain is set by its feedback resistor (R_f) and can be programmed from 10 kΩ to 2 MΩ. The transimpedance gain between the input current and output differential voltage of the TIA is equal to $2 \times R_f$. At the output of the TIA is a switched RC filter. There are four parallel instances of the filter, each of which are connected to the TIA output signal during one of four sampling phases.

The signal chain is kept fully differential throughout the receiver channel in order to enable excellent rejection of common-mode noise as well as noise on power supplies. For simplicity, the scheme with the four parallel filters is shown in Figure 23 for a single-ended representation of the signal chain. The ADCRST signal corresponds to the collection of active phases of four ADCRST pulses: ADCRST0, ADCRST1, ADCRST2, and ADCRST3.
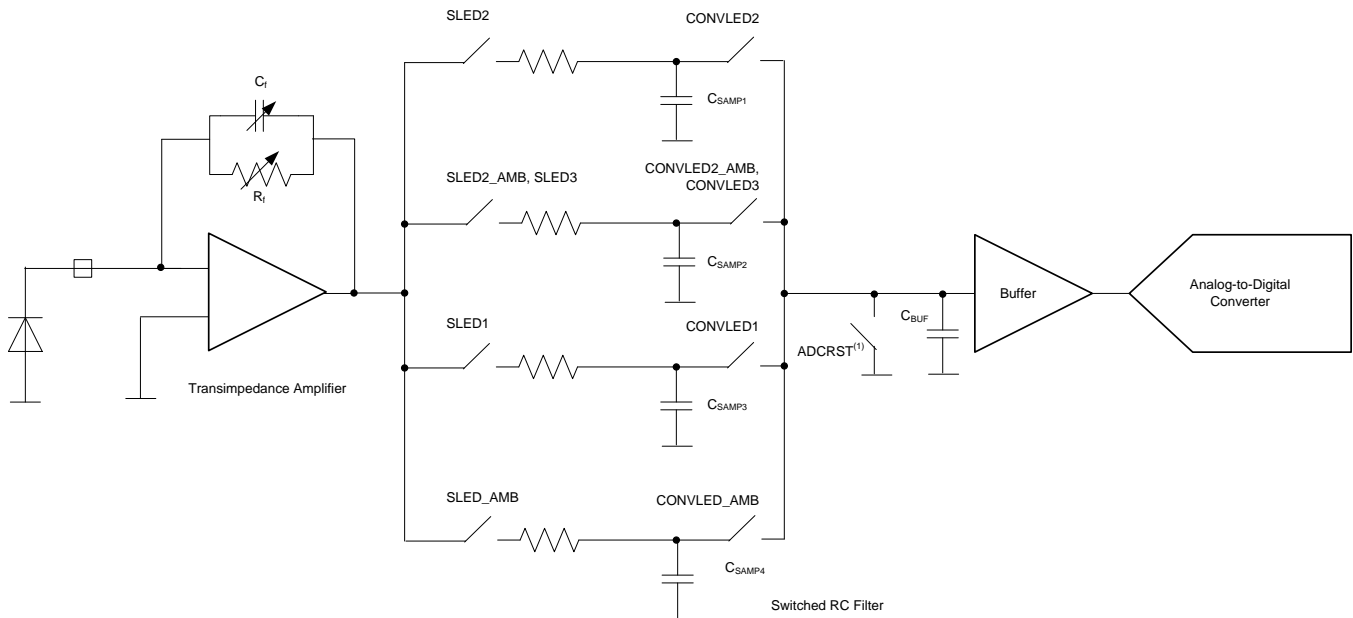
NOTE: For simplicity, this circuit is shown in single-ended format.

(1)   ADCRST corresponds to ADCRST0, ADCRST1, ADCRST2, or ADCRST3.

Figure 23. Four Sampling and Conversion Phases Diagram

Product Folder Links: *AFE4404*

Feature Description (continued)

8.3.1.1 Operation with Two and Three LEDs

The four sampling phases can correspond to either of the following signal state sequences received by the photodiode:

1. 2-LED mode: LED2 → ambient phase 2 → LED1 → ambient phase 1
2. 3-LED mode: LED2 → LED3 → LED1 → ambient

The sequence of the phases within a pulse repetition cycle is shown in Figure 24.
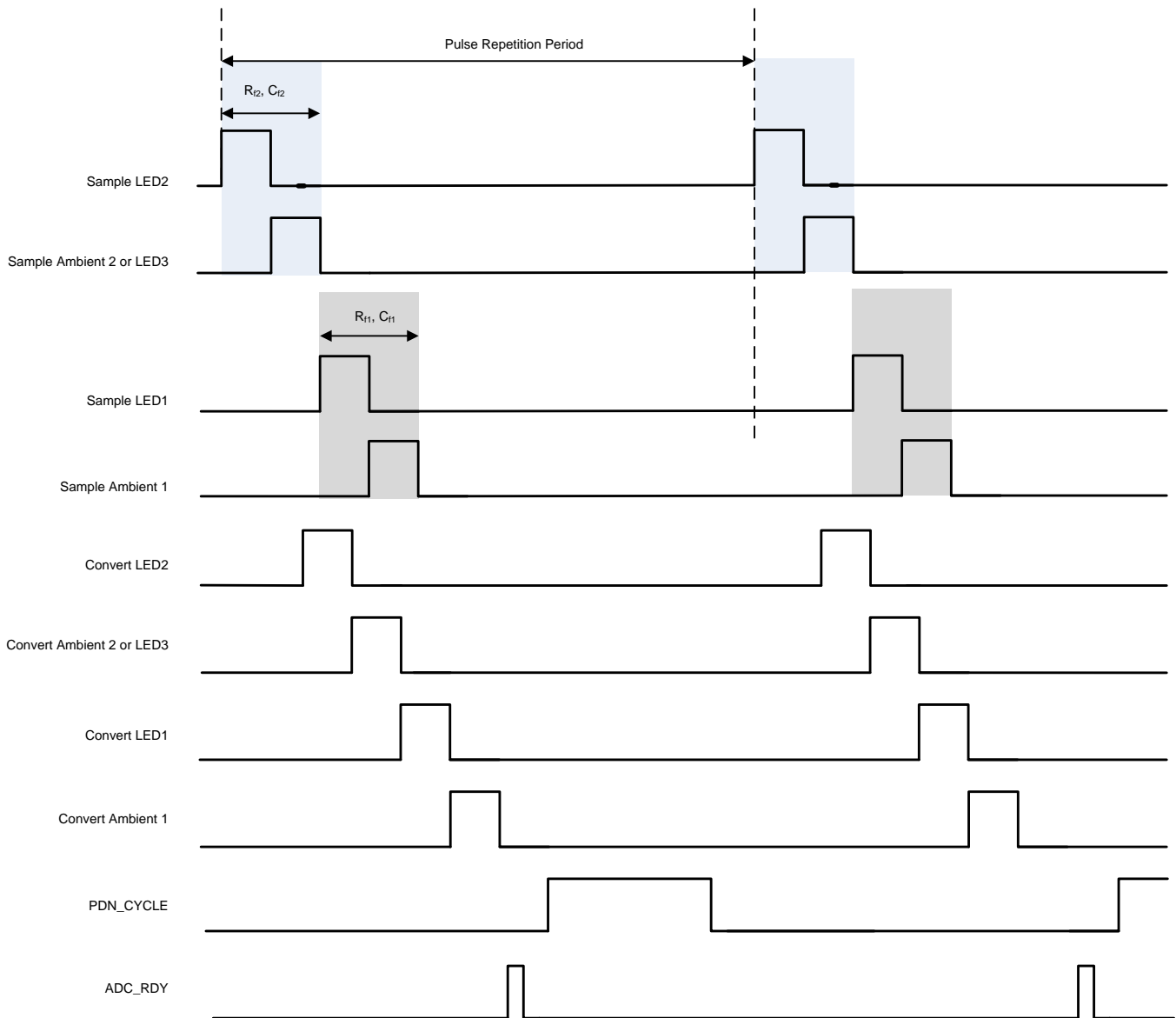
Figure 24. Sequence of Four Sampling and Conversion Phases

In the 2-LED mode, LED1 and LED2 are pulsed during the corresponding sampling instants. In the 3-LED mode, LED1, LED2, and LED3 are pulsed during the corresponding sampling instants. As mentioned in the *TIA Gain Settings* and *Operation with Two and Three LEDs* sections, the TIA gain (R_f) and feedback capacitor (C_f) can be programmed differently between two sets: R_{f1} / C_{f1} and R_{f2} / C_{f2}. The way these sets are applied to the four phases is shown in Figure 24.

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Feature Description (continued)

8.3.1.1.1 LED Current Setting

The default LED current range is from 0 mA to 50 mA. The individual currents of each of the three LEDs can be controlled independently, each with a separate 6-bit control.

Taken as a decimal number, the 6-bit setting provides 63 equal steps between 0 mA and 50 mA. Each increment of the ILED 6-bit code causes the LED current setting to increment by approximately 0.8 mA. For details, see register 22h.

The LED current range can be doubled by setting the ILED_2X bit to 1. The accuracy of higher current settings close to 100 mA can be low because of current saturation of the driver. Each increment of the ILED 6-bit code causes the LED current to increment by approximately 1.6 mA when ILED_2X is set to 1.

8.3.1.2 TIA Gain Settings

The TIA gain is set by programming the value of R_f (the feedback resistor of the TIA). The R_f setting is controlled using the TIA_GAIN register bit. For details see register 21h.

By default, the same TIA_GAIN setting is applied for all four phases of the receiver. Separate gains can be set for two of the four phases by setting the EN_SEP_GAIN bit. When the EN_SEP_GAIN bit is enabled, the TIA_GAIN register controls the R_{f1} setting and the TIA_GAIN_SEP register controls the R_{f2} settings.

Mapping of the R_{f1} / R_{f2} values to the two sets of 3-bit controls is described in Table 50.

8.3.1.3 TIA Bandwidth Settings

TIA bandwidth settings are similar to TIA gain settings. The TIA bandwidth is set by programming the value of C_f (the feedback capacitance of the TIA). The product of R_f and C_f gives the time constant of the TIA and must be set approximately 1/5th (or less) of the LED or sampling pulse durations. This choice of time constant allows the TIA to pass the incoming pulses from the photodiode.

C_f is controlled using the TIA_CF register bit. For details, see register 21.

By default, the same TIA_CF setting is applied for all four phases of the receiver. Similar to the TIA gain settings, a separate C_f can be set for two of the four phases by setting the EN_SEP_GAIN bit. When the EN_SEP_GAIN bit is enabled, the TIA_CF register controls the C_{f1} settings and TIA_CF_SEP controls the C_{f2} settings. Mapping the C_{f1} / C_{f2} values to the two sets of 3-bit controls is the same as illustrated in Table 51.

8.3.2 Power Management

The AFE has three independent supplies for the transmitter, receiver, and I/O.

8.3.2.1 Transmitter Supply (TX_SUP)

The transmitter supply has a range of 3.0 V to 5.25 V. In the most common arrangement, this supply can be the same supply that the anodes of the LEDs are tied to, as shown in Figure 25.
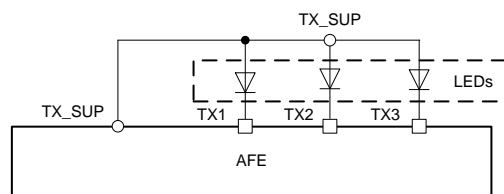
Figure 25. LED to Pin Connections

When the LEDs must be tied to a different supply, care must be taken to ensure that the LED supply is within 0.3 V of TX_SUP. This consideration of the LED supply voltage prevents the electrostatic discharge (ESD) diodes inside the AFE from turning on during the off state of the LEDs.

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Feature Description (continued)

8.3.2.2 Receiver Supply (RX_SUP)

The receiver supply has a range of 2.0 V to 3.6 V. The AFE has internal low-dropout (LDO) regulators operating at 1.8 V that regulate both the analog and digital blocks inside the AFE. This rejection of supply noise from the internal LDOs, coupled with the differential nature of the architecture, enables excellent noise rejection on the supplies (for instance, 50-Hz noise).

8.3.2.3 I/O Supply (IO_SUP)

The I/O supply can either be tied to RX_SUP or can be separately driven. The motivation for a separate I/O supply is to interface with certain microcontrollers (MCUs) that require a 1.8-V I/O current. In this case, IO_SUP can be driven separately from RX_SUP and can be tied to 1.8 V.

8.3.2.4 Boost Converters Selection

If the supply voltage for TX_SUP (and the LEDs) is unavailable in the system, a boost converter may be required to generate the supply voltage. TI has a portfolio of boost converters from which an appropriate device can be selected. Some choices are listed in Table 1.

Table 1. TI Boost Converter Details[1]

TI PART NUMBER	SIZE (mm, L × W × H)	INPUT SUPPLY (V)	OUTPUT SUPPLY	TYPICAL QUIESCENT CURRENT (µA)	EXTERNAL COMPONENTS
TPS61254	1.2 × 1.3 × 0.625	2.3 to 5.5	Different parts with a fixed voltage up to 5 V	36	2 capacitors, 1 inductor
TPS61240	0.9 × 1.3 × 0.625	2.3 to 5.5	5 V (fixed)	30	2 capacitors, 1 inductor
TPS61252	2 × 2 × 0.75	2.3 to 6	Adjustable up to 6.5 V	30	3 capacitors, 1 inductor, 4 resistors
TPS61220	2 × 2.2 × 1	0.7 to 5.5	Adjustable from 1.8 V to 6 V	5.5	2 capacitors, 1 inductor, 2 resistors

(1)   For the most current information, see the TI data sheets corresponding to each device (available for download from www.ti.com).

8.3.3 Offset Cancellation DAC

A typical optical heart-rate signal has a dc component and an ac component. Although a higher TIA gain maximizes the ac signal at the AFE output, the magnitude of the dc component limits the maximum gain possible in the TIA. In order to decouple the affect of the dc level on the allowed ac signal gain, a current digital-to-analog converter (DAC) is placed at the input of the device. By setting a programmable cancellation current (based on the dc current signal level), the effective signal that is gained up by the TIA can be reduced. This reduction in the effective signal current into the TIA results in the ability to set a higher TIA gain than what is otherwise possible without enabling the offset correction. In each of the four phases of operation, a separate programmable current value can be set by programming four different sets of register bits. These cancellation currents are automatically presented to the input of the TIA in the appropriate phase. The ability to set a different cancellation current in each of the four phases can be used to cancel out the ambient current in the ambient phase. In the LED on phase, this ability can be used to cancel out the sum of the ambient current and dc current of the heart-rate signal. The polarities of the signal current and offset cancellation current is illustrated in Figure 26. The polarity of the offset cancellation current can be reversed by programming the POL_OFFDAC bits.

With zero input current and zero current in the offset cancellation DAC, the output of the AFE will be close to zero. Based on the channel offset, the output voltage for zero input current could be a small positive or negative value, usually in the range of several mV. With the photodiode connected as shown in Figure 26 and a signal current coming from the photodiode, the output code of the device is expected to be positive with the offset cancellation DAC set to zero (I_{offset} = 0). With I_{offset} set negative (POL_OFFFAC = 1), a dc offset can be subtracted from the signal and the ac signal can be amplified with a higher gain than what is otherwise possible.
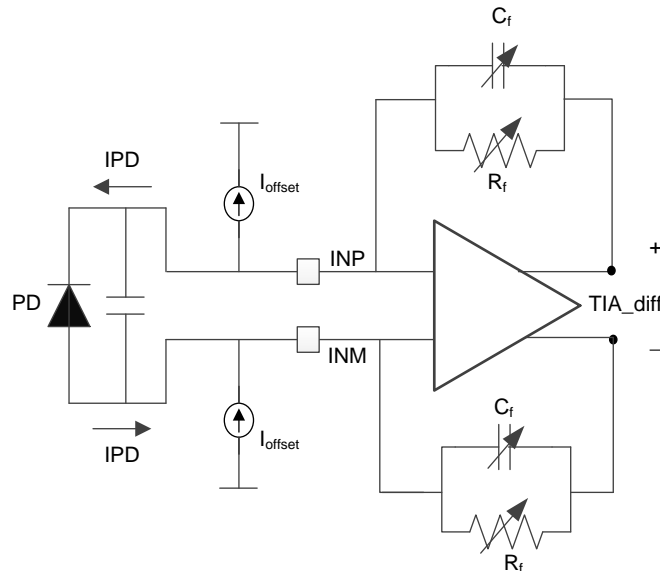
Figure 26. Offset Cancellation Current Polarity Diagram

A breakdown of the signal current and voltage levels is provided in Table 2 for a variety of signal levels. In Table 2, the current transfer ratio (CTR) is used to describe the relationship between the set LED current and the resulting photodiode current (IPD). CTR is the ratio of the photodiode current for a given LED current and is a function of the optical and mechanical parameters as well as human physiology.

Table 2. Signal Current and Voltage Levels for a Hypothetical Use Case[1]

PHASE	ILED (mA)	CTR (µA / mA)	I_{sig} (µA)	I_{amb} (µA)	IPD (µA)	I_OFFDAC (µA)	I_{eff} (µA)	R_f (MΩ)	TIA_diff (V)
LED2	25	0.025	0.625	1	1.625	−1.4	0.225	1	0.45
LED3	50	0.025	1.25	1	2.25	−1.87	0.38	0.5	0.38
LED1	12.5	0.025	0.3125	1	1.3125	−0.93	0.3825	0.5	0.3825
AMB1	0	0.025	0	1	1	−0.93	0.07	2	0.28

(1) ILED is the set LED current; CTR is the current transfer ratio (in µA / mA); I_{sig} is the photodiode signal current resulting from LED pulsing (I_{sig} = ILED × CTR); I_{amb} is the current in the photodiode resulting from ambient light (that is present in all phases and adds to I_{sig}); IPD is the total input current (I_{sig} + I_{amb}); I_OFFDAC is the current setting of the offset cancellation DAC; I_{eff} is the effective current after offset cancellation (I_{sig} + I_OFFDAC); R_f is the TIA gain setting; and TIA_diff is the output differential signal of the TIA (note that this signal must be within the range of ±1 V).

8.3.3.1 Offset Cancellation DAC Controls

The I_OFFDAC bits control the magnitude of the current subtracted (or added) at the TIA input. The POL_OFFDAC bits control the polarity of the current and determine whether the current is subtracted from or added to the input. For details, see register 3Ah.

8.3.4   Analog-to-Digital Converter (ADC)

The AFE has an ADC that provides a 22-bit representation of the current from the photodiode. The ADC codes corresponding to the various sampling phases can be read out from 24-bit registers in twos complement format. The ADC full-scale input range is ±1.2 V and spans bits 21 to 0. The mapping of the ADC input voltage to the ADC code is shown in Table 3.

Table 3. Mapping the ADC Input Voltage to the ADC Code

DIFFERENTIAL INPUT VOLTAGE AT ADC INPUT	24-BIT ADC OUTPUT CODE
–1.2 V	111000000000000000000000
$(-1.2 / 2^{21})$ V	111111111111111111111111
0	000000000000000000000000
$(1.2 / 2^{21})$ V	000000000000000000000001
1.2 V	000111111111111111111111

The two MSBs of the 24-bit word serve as sign-extension bits to the 22-bit ADC code and are equal to the MSB of the 22-bit ADC code when the input to the ADC is within its full-scale range, as shown in Table 4.

Table 4. Using Sign-Extension Bits to Determine the Input Operating Voltage

BITS 23-21	INPUT STATUS
000	Positive and lower than positive full-scale (within full-scale range)
111	Negative and higher than negative full-scale (within full-scale range)
001	Positive and higher than positive full-scale (outside full-scale range)
110	Negative and lower than negative full-scale (outside full-scale range)

Noted that the TIA has an operating range of ±1 V even though the ADC input full-scale range is ±1.2 V, as shown in Figure 27. When setting the TIA gain, ensure that the signal at the TIA output does not exceed ±1 V.

1.2 V	ADC Max (Differential)
1 V	TIA Max (Differential)
0 V	
-1 V	TIA Min (Differential)
-1.2 V	ADC Min (Differential)
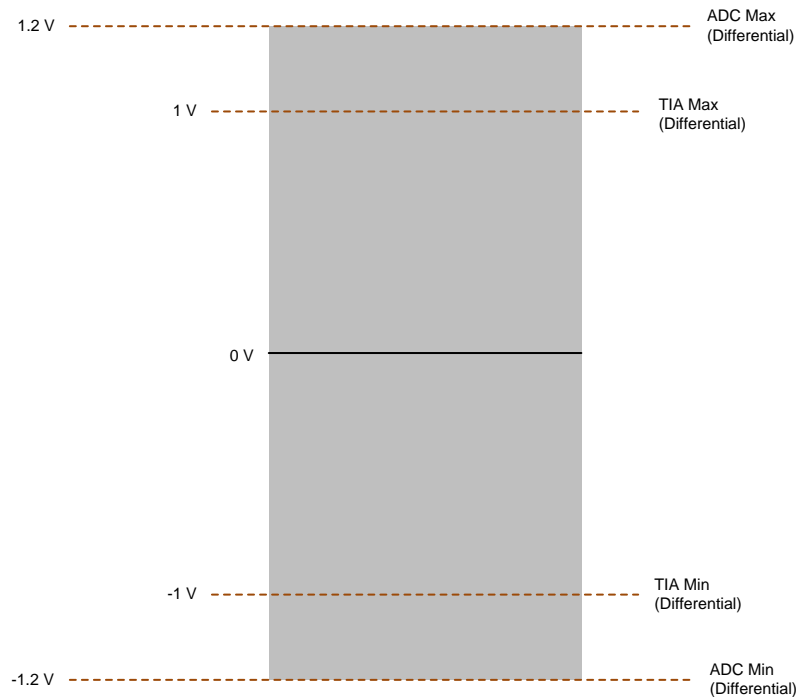
Figure 27. TIA and ADC Dynamic Ranges

8.3.5 I²C Interface

The AFE has an I²C interface for communication. The I2C_CLK and I2C_DAT lines require external pullup resistors to IO_SUP. See the I²C protocol standards documents for details of the I²C interface. This section only describes certain key features of the interface. The data on I2C_DAT must be stable during the high level of I2C_CLK and may transition during the low level of I2C_CLK, as shown in Figure 28.
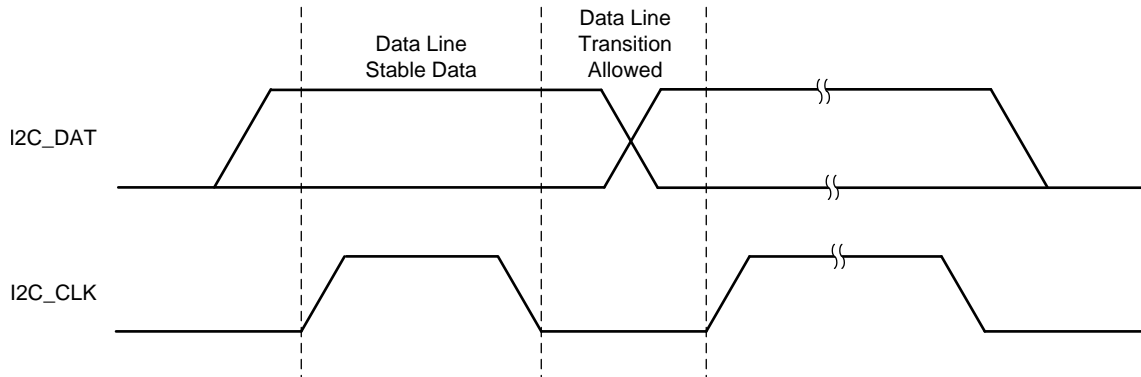
Figure 28. Allowed Transition of I2C_DAT while Transmission of Data Bits

The start condition is indicated by a high-to-low transition of the I2C_DAT line when the I2C_CLK is high. A stop condition is indicated by a low-to-high transition of the I2C_DAT line when the I2C_CLK is high. Figure 29 shows the start and stop conditions.
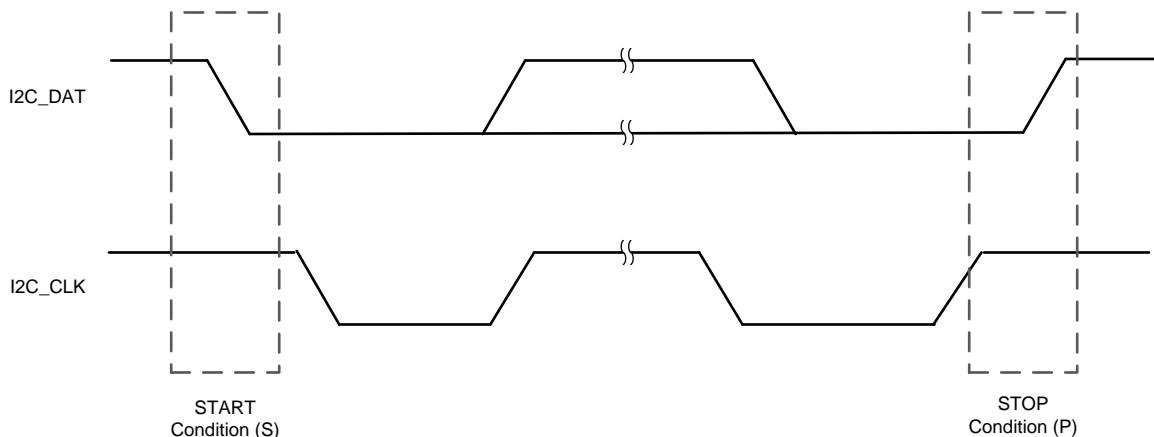
Figure 29. Transition of I2C_DAT during Start and Stop Conditions

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With the previously mentioned protocols for data, start, and stop conditions in place, the write and read operations are as shown in Figure 30 and Figure 31, respectively. In Figure 30 and Figure 31, the slave address for the AFE (indicated as SA6 to SA0) is a 7-bit representation of address 58h. The R/W bit is the read/write bit and is set to '1' for Read and '0' for Write. Only the ADC output registers (addressed from 2Ah to 2Fh) can be read out without the need for setting the REG_READ bit. Prior to reading out any other register, the REG_READ bit needs to be additionally set to '1'. In Figure 30 and Figure 31, the activity performed by the host is shown in black whereas activity from the AFE is shown in red. Thus, after the host sends the slave address during a write operation, the AFE pulls the I2C_DAT line low (shown as ACK) if the slave address matches 58h. Similarly, the host pulls the I2C_DAT line high (shown as NACK) as acknowledgment of a successfully completed read operation involving three bytes of data. Continuous read/write mode is not supported.
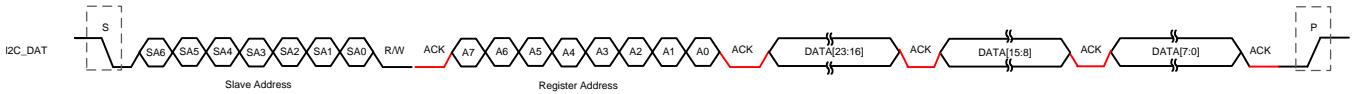
(1)   Activity performed by the host is shown in black whereas activity from the AFE is shown in red. Continuous read/write mode is not supported.

Figure 30. I²C Write Option Timing

Figure 31. I²C Read Option Timing

8.3.6   Timing Engine

The AFE has a fully-integrated timing engine that can be programmed to generate all clock phases for synchronized transmit drive, receive sampling, and data conversion. To enable the timing engine (after powering up the device), enable the TIMEREN bit.

8.3.6.1   Timer and PRF Controls

The timing engine inside the AFE has a 16-bit counter. The duration of the count with respect to an internal clock (the timer clock) determines the pulse repetition period. The pulse repetition frequency (PRF) can be set using the PRPCT register bits that represent the high value of the counter (the low value of the counter is 0). The counter automatically counts until reaching PRPCT and then returns to 0 to start the next count. To suspend the count and keep the counter in reset state, enable the TM_COUNT_RST bit.

8.3.6.2 Timing Control Registers

The start and stop counts for the various dynamic signals generated by the timing engine are shown in Table 5. The timing edge numbers are in reference to Figure 32.

Table 5. Timing Register and Edge Details

TIMING SIGNAL	DESCRIPTION	REGISTER ADDRESS (Hex)	TIMING EDGE
LED2STC	Sample LED2 start	1h	TE3
LED2ENDC	Sample LED2 end	2h	TE4
LED1LEDSTC	LED1 start	3h	TE17
LED1LEDENDC	LED1 end	4h	TE18
ALED2STC\LED3STC	Sample ambient 2 (or sample LED3) start	5h	TE11
ALED2ENDC\LED3ENDC	Sample ambient 2 (or sample LED3) end	6h	TE12
LED1STC	Sample LED1 start	7h	TE19
LED1ENDC	Sample LED1 end	8h	TE20
LED2LEDSTC	LED2 start	9h	TE1
LED2LEDENDC	LED2 end	Ah	TE2
ALED1STC	Sample ambient 1 start	Bh	TE25
ALED1ENDC	Sample ambient 1 end	Ch	TE26
LED2CONVST	LED2 convert phase start	Dh	TE7
LED2CONVEND	LED2 convert phase end	Eh	TE8
ALED2CONVST\LED3CONVST	Ambient 2 (or LED3) convert phase start	Fh	TE15
ALED2CONVEND\LED3CONVEND	Ambient 2 (or LED3) convert phase end	10h	TE16
LED1CONVST	LED1 convert phase start	11h	TE23
LED1CONVEND	LED1 convert phase end	12h	TE24
ALED1CONVST	Ambient 1 convert phase start	13h	TE29
ALED1CONVEND	Ambient 1 convert phase end	14h	TE30
ADCRSTSTCT0	ADC reset phase 0 start	15h	TE5
ADCRSTENDCT0	ADC reset phase 0 end	16h	TE6
ADCRSTSTCT1	ADC reset phase 1 start	17h	TE13
ADCRSTENDCT1	ADC reset phase 1 end	18h	TE14
ADCRSTSTCT2	ADC reset phase 2 start	19h	TE21
ADCRSTENDCT2	ADC reset phase 2 end	1Ah	TE22
ADCRSTSTCT3	ADC reset phase 3 start	1Bh	TE27
ADCRSTENDCT3	ADC reset phase 3 end	1Ch	TE28

When three LEDs are used within a single period, the Ambient2 phase is replaced by the LED3 phase. The timing controls for driving the third LED are as shown in Table 6.

Table 6. Timing Controls for Driving the Third LED

TIMING SIGNAL	DESCRIPTION	REGISTER ADDRESS (Hex)	TIMING EDGE
LED3LEDSTC	LED3 start	36h	TE9
LED3LEDENDC	LED3 end	37h	TE10

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The timing diagram for when all three LEDs are active is shown in Figure 32.
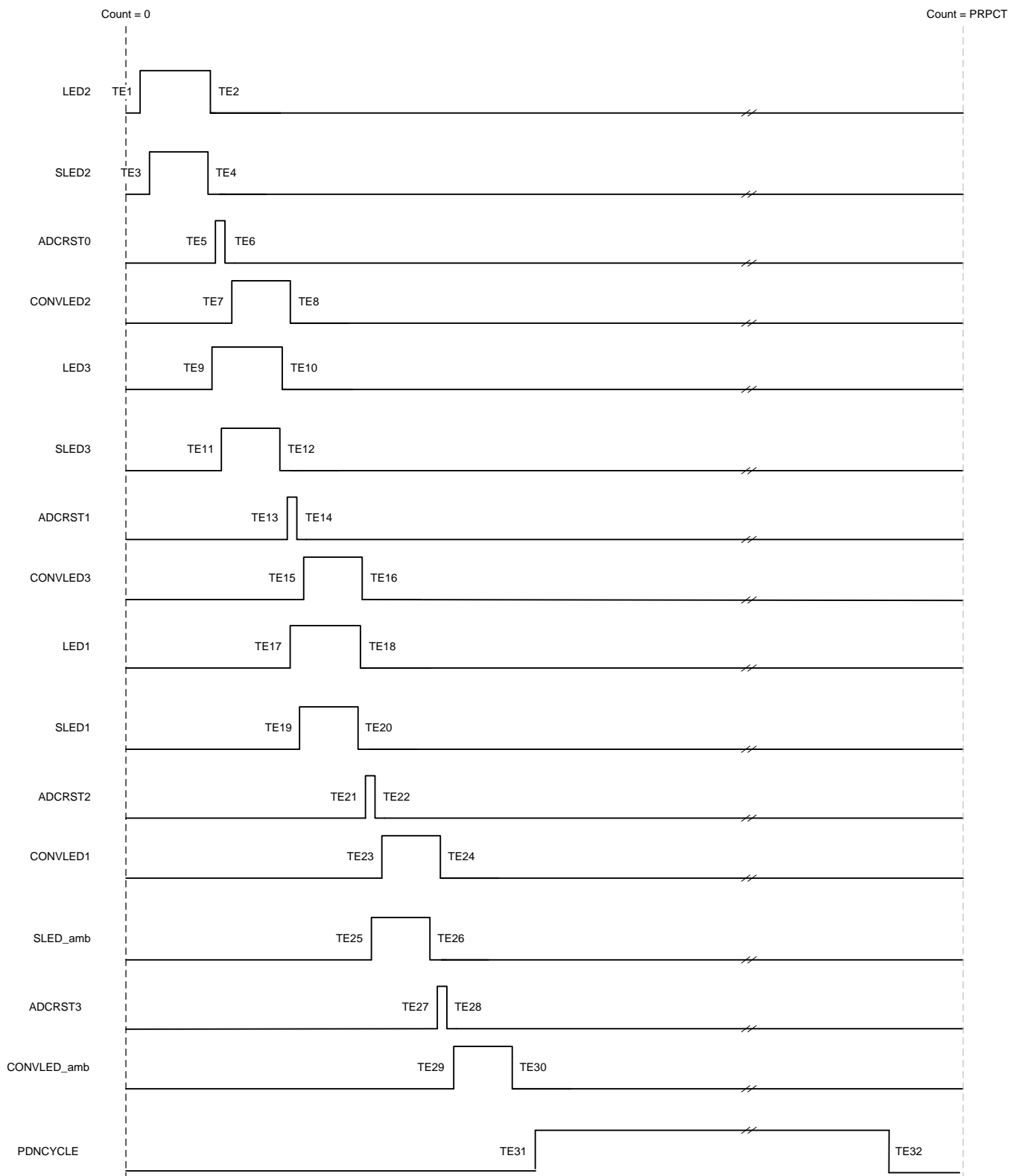
Figure 32. Timing Diagram

8.3.6.3 Receiver Timing

The timing engine can be programmed to set the different phases of the receiver. The relative timings of the LED phase, sampling phase, ADC reset phase, and ADC conversion phases are shown in Figure 33 and Table 7.
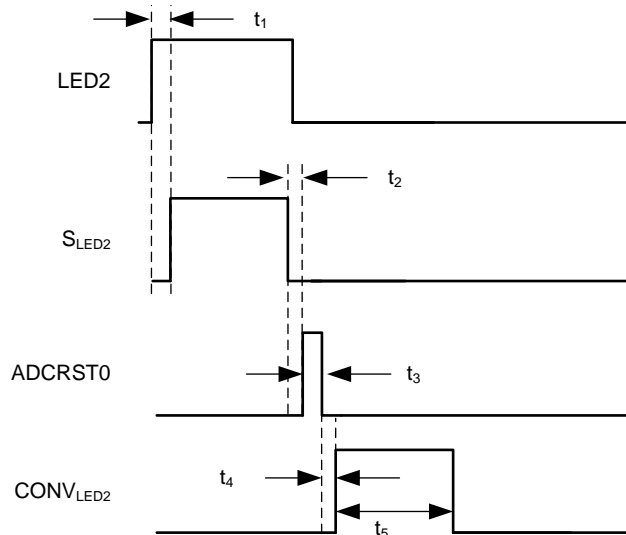
Figure 33. Receiver Timing Guidelines

Table 7. Receiver Timing Details

		MIN	MAX	UNIT
t_1	Start of LED to start of sampling	Max [25, (0.2 × LED pulse duration)]		µs
t_2	End of LED to start of ADC reset phase	2		Counts[1]
t_3	Duration of ADC reset phase	6		Counts
t_4	End of ADC reset phase to start of ADC conversion phase	2	2	Count
t_5	Duration of ADC conversion phase[2]	(NUMAV + 2) × 200 × t_{ADC} + 15[3]		µs

(1) Refers to one clock period of CLK_TE.
(2) See Figure 36 for notations of the clocking domain.
(3) $t_{ADC} = 1 / f_{ADC}$.

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The fourth ADCRST signal (ADCRST3) in a period also defines the start of the ADC_RDY pulse. The rising edge of the ADC_RDY signal can be used as an interrupt by the MCU to readout the registers corresponding to the preceding four conversions in that period. If any of the four conversion phases are not needed, then their duration can be set to 0. However, the corresponding ADCRSTx pulse must still be defined. All four ADCRSTx pulses must be defined in order to generate the ADC_RDY pulse. A scheme of the ADC_RDY pulse generation is shown in Figure 34. The ADC_RDY pulse timing is shown in Table 8.
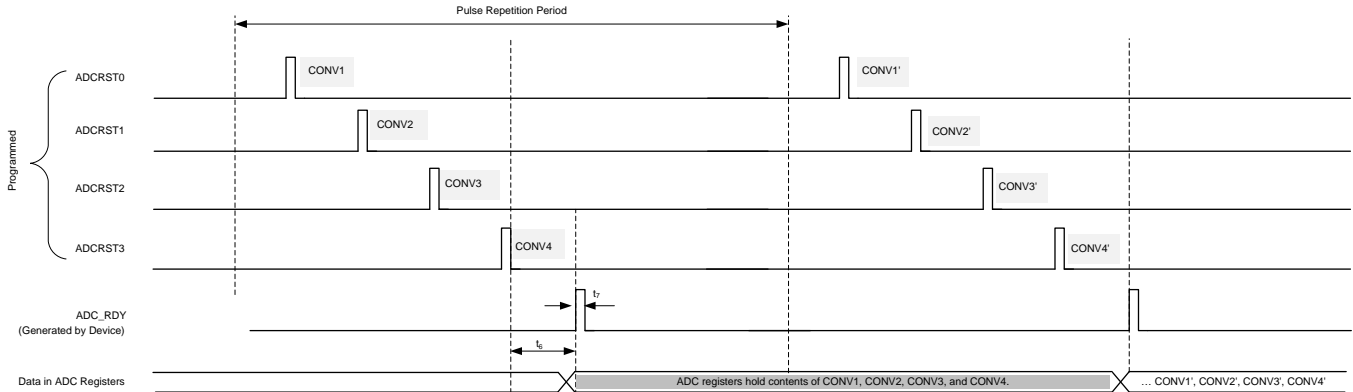
Figure 34. ADC_RDY Generation Scheme

Table 8. ADC_RDY Timing Details

		TYP	MAX	UNIT
t_6	End of fourth ADC reset phase to start of ADC_RDY pulse	$(NUMAV + 1) \times 200 \times t_{ADC}$	$(NUMAV + 2) \times 200 \times t_{ADC} + 15$	µs
t_7	ADC_RDY pulse duration	$t_{ADC}^{(1)}$		µs

(1) If a larger pulse duration is needed for the ADC_RDY interrupt, use PROG_TG_EN to enable a programmable timing signal to come out of the ADC_RDY pin. The location of the signal can be set using the PROG_TG_STC and PROG_TG_ENDC counts.

8.3.6.4 Dynamic Power-Down Timing

The dynamic power-down feature can be used to shut down the receiver inside every cycle to save power, as shown in Figure 35 and Table 9.
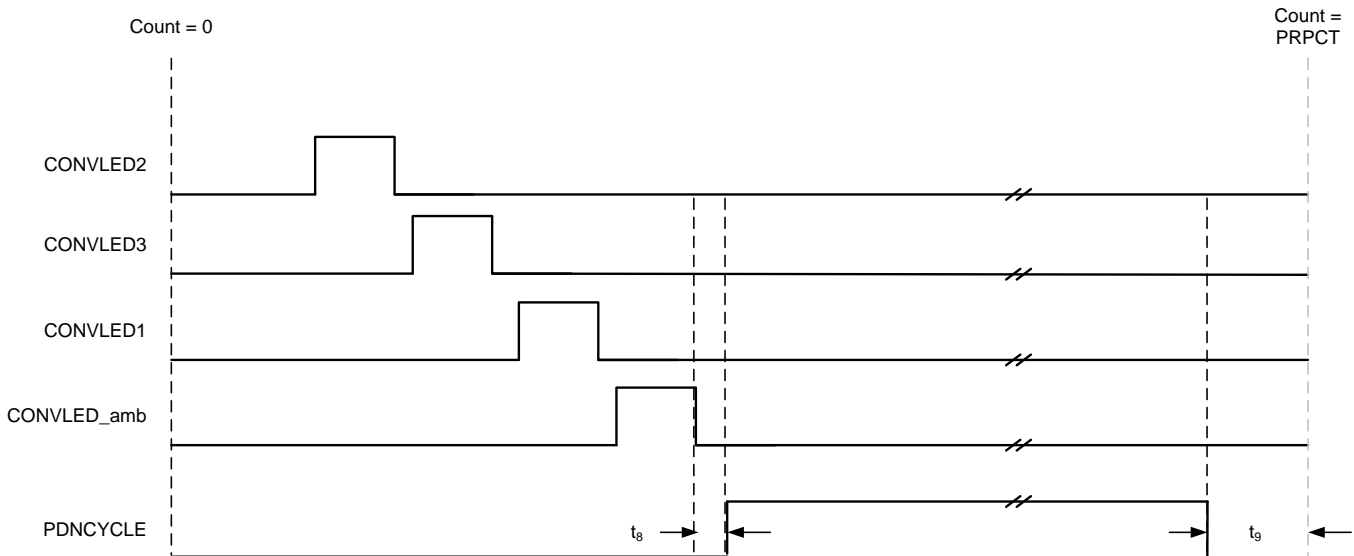
Figure 35. Dynamic Power-Down Timing Diagram

Table 9. Dynamic Power-Down Timing Details

		MIN	UNIT
t_8	End of 4th conversion phase to the start of PDNCYCLE	200	µs
t_9	End of PDNCYCLE to start of next period	200	µs

The timing controls for the PDNCYCLE pulse are shown in Table 10.

Table 10. Timing Controls for Dynamic Power-Down

TIMING SIGNAL	DESCRIPTION	REGISTER ADDRESS (Hex)	TIMING EDGE[1]
PDNCYCLESTC	Dynamic power-down start	32h	TE31
PDNCYCLEENDC	Dynamic power-down end	33h	TE32

(1)   See Figure 32.

8.3.6.5 Sample Register Values

Table 11 lists a sample of the register settings for generating the different timing signals. These sample settings correspond to CLK_INT = 4 MHz and a PRF of 100 Hz. Three LEDs are used in a cycle, each with a duty cycle of 1%, corresponding to a pulse duration of 100 µs. The conversion durations are set in order to accommodate four averages (NUMAV = 3). Two cases are described in Table 11: one for CLKDIV_PRF = 1 (CLK_TE = 4 MHz) and the other for CLKDIV_PRF = 16 (CLK_TE = 250 kHz).

Table 11. Sample Register Settings

SIGNAL[1]	REGISTER FIELD	NO DIVISION OF CLOCK TO TIMING ENGINE CLOCK (CLKDIV_PRF = 1)		ADC CLOCK TO TIMING ENGINE CLOCK DIVIDED BY 16 (CLKDIV_PRF = 16)	
		TIME DURATION (µs)	REGISTER SETTING[2]	TIME DURATION (µs)	REGISTER SETTING[2]
PRF COUNTER	PRPCT	10000	39999[3]	10000	2499[3]
LED2	LED2LEDSTC	100	0	100	0
	LED2LEDENDC		399		24
S_{LED2}	LED2STC	75	100	72	7
	LED2ENDC		399		24
ADCRST0	ADCRSTSTCT0	1.75	401	4	26
	ADCRSTENDCT0		407		26
$CONV_{LED2}$	LED2CONVST	265	409	268	28
	LED2CONVEND		1468		94
LED3	LED3LEDSTC	100	401	100	26
	LED3LEDENDC		800		50
S_{LED3}	ALED2STC\LED3STC	75	501	72	33
	ALED2ENDC\LED3ENDC		800		50
ADCRST1	ADCRSTSTCT1	1.75	1470	4	96
	ADCRSTENDCT1		1476		96
$CONV_{LED3}$	ALED2CONVST\LED3CONVST	265	1478	268	98
	ALED2CONVEND\LED3CONVEND		2537		164
LED1	LED1LEDSTC	100	802	100	52
	LED1LEDENDC		1201		76
S_{LED1}	LED1STC	75	902	72	59
	LED1ENDC		1201		76
ADCRST2	ADCRSTSTCT2	1.75	2539	4	166
	ADCRSTENDCT2		2545		166
$CONV_{LED1}$	LED1CONVST	265	2547	268	168
	LED1CONVEND		3606		234
S_{LED_AMB}	ALED1STC	75	1303	72	85
	ALED1ENDC		1602		102
ADCRST3	ADCRSTSTCT3	1.75	3608	4	236
	ADCRSTENDCT3		3614		236
$CONV_{LED\_AMB}$	ALED1CONVST	265	3616	268	238
	ALED1CONVEND		4675		304
PDNCYCLE	PDNCYCLESTC	8431.25	5475	8384	354
	PDNCYCLEENDC		39199		2449

(1)   For signal names, see Figure 23.
(2)   Time duration = (end count – start count + 1) / f_{TE}.
(3)   For PRPCT, start count = 0.

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The timing described in Table 11 minimizes the active time, thereby enabling the signal chain to be in the dynamic power-down state for the maximum fraction of time. In this timing, the LED active phase overlaps with the conversion phase corresponding to a previous LED. The ground bounce from the LED switching can couple into the receiver and cause a small interference between one phase and the next. In most intended applications, this bounce is not expected to cause any problems. However, if the lowest level of interference across phases must be attained, the timing registers can be programmed as shown in Table 12.

Table 12. Sample Register Settings for Low Interference Across Phases

SIGNAL[1]	REGISTER FIELD	NO DIVISION OF CLOCK TO TIMING ENGINE CLOCK (CLKDIV_PRF = 1)	
		TIME DURATION (μs)	REGISTER SETTING
PRF COUNTER	PRPCT	10000	39999
LED2	LED2LEDSTC	99.75	0
	LED2LEDENDC		398
S_{LED2}	LED2STC	74.75	100
	LED2ENDC		398
ADCRST0	ADCRSTSTCT0	1.75	5600
	ADCRSTENDCT0		5606
$CONV_{LED2}$	LED2CONVST	115	5608
	LED2CONVEND		6067
LED3	LED3LEDSTC	99.75	400
	LED3LEDENDC		798
S_{LED3}	ALED2STC\ LED3STC	74.75	500
	ALED2ENDC\ LED3ENDC		798
ADCRST1	ADCRSTSTCT1	1.75	6069
	ADCRSTENDCT1		6075
$CONV_{LED3}$	ALED2CONVST\ LED3CONVST	115	6077
	ALED2CONVEND\ LED3CONVEND		6536
LED1	LED1LEDSTC	99.75	800
	LED1LEDENDC		1198
S_{LED1}	LED1STC	74.75	900
	LED1ENDC		1198
ADCRST2	ADCRSTSTCT2	1.75	6538
	ADCRSTENDCT2		6544
$CONV_{LED1}$	LED1CONVST	115.25	6546
	LED1CONVEND		7006
S_{LED_AMB}	ALED1STC	74.75	1300
	ALED1ENDC		1598
ADCRST3	ADCRSTSTCT3	1.75	7008
	ADCRSTENDCT3		7014
$CONV_{LED\_AMB}$	ALED1CONVST	115	7016
	ALED1CONVEND		7475
PDNCYCLE	PDNCYCLESTC	7881.25	7675
	PDNCYCLEENDC		39199

(1) For signal names, see Figure 23.

8.4 Device Functional Modes

8.4.1 Power Modes

The AFE has the following power modes:

1. Normal mode.
2. Hardware power-down mode (PWDN): this mode is set using the RESETZ pin. When the RESETZ pin is pulled low for more than 200 µs, the device enters hardware power-down mode where the power consumption is very low (of a few µA).
3. Software power-down mode (PDNAFE) using a register bit.
4. Dynamic power-down mode: this mode is enabled by setting the start and end points of the PDN_CYCLE signal that is controlled using the timing engine. During the PDN_CYCLE high phase, the functional blocks (as selected by the DYNAMICx bits) are powered down. When powering down the TIA in dynamic power-down mode, consideration must be given to the dynamics of the photodiode. When the TIA is powered down, the feedback mechanism is no longer available to maintain zero bias across the photodiode, resulting in a voltage drift across the photodiode. When the AFE comes out of dynamic power-down into active mode, a transient recovery time for the photodiode results. Additionally, the INP, INM pins can be shorted through a switch to an internal reference voltage (VCM) to keep the photodiode in zero bias whenever the TIA is in power-down mode. Maintaining zero bias across the photodiode is accomplished by setting the ENABLE_INPUT_SHORT bit to 1. By setting this bit in conjunction with the DYNAMIC3 bit, the dynamics of the photodiode can be better controlled during the dynamic power-down mode.

8.4.2 RESET Modes

The AFE has internal registers that must be reset before valid operation. There are two ways to reset the device:

1. Either through the RESETZ pin (a reset signal can be issued by pulsing the RESETZ pin low for a duration of time between 25 to 50 µs) or
2. A software reset via the SW_RESET register bit.

8.4.3 Clocking Modes

The AFE has an internal oscillator that can generate a 4-MHz clock. This clock can be made to come out of the CLK pin for use by the rest of the system. The default mode is to use an external clock. The frequency range of this external clock is between 4 MHz to 60 MHz. A programmable internal division ratio between 1 to 12 must be set so that the divided clock is between 4 MHz to 6 MHz. For high-accuracy measurements, operating the AFE using an input (external) clock with high accuracy is preferable. If a high-accuracy measurement is required when using the internal oscillator, a correction scheme can be used in the MCU to digitally compensate for the inaccuracy in the oscillator. One method of this approach is to accurately estimate the PRF by measuring the ADC_RDY periodicity in terms of a high-accuracy MCU clock (for example, a 32-kHz clock) to establish the accurate PRF. This information can then be used to digitally correct the heart rate computation.

8.4.4 PRF Programmability

By default, the internal clock is 4 MHz. This clock also goes to the timing engine that has a 16-bit counter. The maximum setting of this counter (all 16 bits set to 1) determines the lowest value of PRF, resulting in a minimum PRF of 61 Hz. To extend the lower range of PRF, an independent programmable divider is introduced in the clock going to the timing engine. By programming this divider between 1 to 16 with the CLKDIV_PRF register control, the lower range of PRF can be extended from 61 Hz to approximately 4 Hz (limit the minimum PRF to 10 Hz). The various clocking domains and controls are described in Figure 36 and Table 13.

Device Functional Modes (continued)
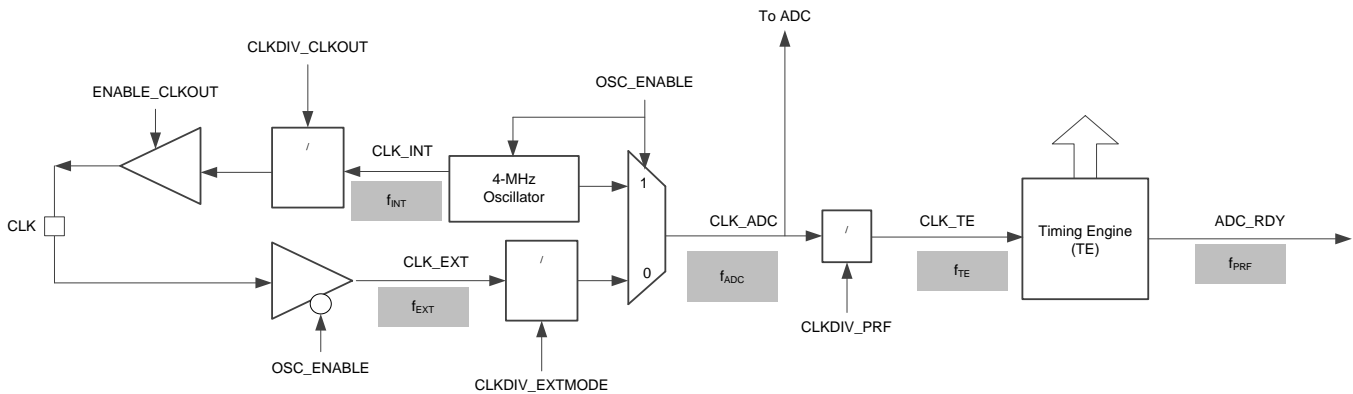
Figure 36. Clocking Domains Diagram

Table 13. Clock Domains and Operating Ranges

CLOCK	DESCRIPTION	FREQUENCY	FREQUENCY RANGE	COMMENTS
CLK_INT	Clock generated by the internal oscillator	f_{INT}	4 MHz [(1)]	Internal clock when the oscillator is enabled
CLK_EXT	External clock	f_{EXT}	4 MHz to 60 MHz	Set the division ratio with CLKDIV_EXTMODE so that CLK_ADC is 4 MHz to 6 MHz
CLK_ADC	Clock used by the ADC for conversion	f_{ADC}	4 MHz to 6 MHz	Selected as either an internal clock or a divided version of the external clock
CLK_TE	Clock used by the timing engine	f_{TE}	f_{ADC} divided by 1 to 16	Division ratio is set by CLKDIV_PRF
ADC_RDY	Interrupt to MCU at the same rate as the PRF	f_{PRF}	Limit to 10 Hz-1000 Hz, limited to 1000 / (division ratio as set by CLKDIV_PRF)	Set by PRPCT and f_{TE}

(1)   See the *Electrical Characteristics* table for the accuracy of the internal oscillator.

8.4.5 Averaging Modes

To reduce the noise, the input to the ADC (sampled on the CSAMPx capacitors) can be converted by the ADC multiple times and averaged. The number of averages is set using the NUMAV register control based on Equation 1:

Number of Averages = (NUMAV + 1)   (1)

By default, NUMAV = 0. Therefore, the default mode corresponds to when the ADC converts its input one time in each of the four phases and stores the content in the register corresponding to that phase.

When NUMAV is programmed (for example if NUMAV = 3), the ADC converts its input four times in each phase, averages the four conversions, and stores the averaged value in the register corresponding to that phase.

Averaging only helps in reducing ADC noise and not the front end noise because the input to the ADC is the same sampled voltage across all the ADC conversions used to generate the average (this voltage corresponds to the voltage sampled on the four CSAMPx capacitors in Figure 23). The number of samples that can be averaged ranges from 1 to 16 (when NUMAV is programmed from 0 to 15). A higher number of averages results in larger conversion times; see Table 7.

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Averaging is implemented in the following manner:

The number of ADC samples corresponding to the number of averages (NUMAV + 1) are accumulated, as shown in Equation 2.

$$\text{SUMADC} = \sum_{i=1}^{(NUMAV+1)} (ADCi)$$

where

- ADCi = the ith sample converted by the ADC.   (2)

The accumulator output (SUMADC) is then divided by a factor *D* that is obtained by D = 128 ÷ X , with X being an integer.

The averaged output is shown in Equation 3:

ADCOUT = SUMADC ÷ D

where

- D = 128 ÷ X, with X being an integer.   (3)

This implementation gives an averaging function that is exact when the number of averages is a power of 2 but deviates from ideal values for other settings, as shown in Table 14.

Table 14. Averaging Mode Settings

NUMAV	NUMBER OF AVERAGES	INTEGER (X)	DIVISION FACTOR (D)
0	1	128	1.0
1	2	64	2.0
2	3	43	2.97
3	4	32	4.0
4	5	26	4.92
5	6	21	6.10
6	7	18	7.11
7	8	16	8.0
8	9	14	9.14
9	10	13	9.85
10	11	12	10.67
11	12	11	11.64
12	13	10	12.8
13	14	9	14.22
14	15	9	14.22
15	16	8	16.0

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8.4.6 Decimation Mode

The AFE4404 has a decimation mode that can be used to improve the performance at low pulse repetition frequencies (PRFs). In this mode, up to N (N = 2, 4, 8, or 16) consecutive data samples can be averaged. The averaged output comes out one time every N clock cycles. The ADC_RDY frequency also reduces to PRF / N.

A timing diagram is shown in Figure 37 for where the decimation factor = 4 and PRF = 100 Hz. Figure 37 is only intended to illustrate the change in periodicity of ADC_RDY and the update rate of the registers relative to the pulse repetition period. However, the timing of all other signals continues to be as per the descriptions mentioned in the *Timing Engine* section.
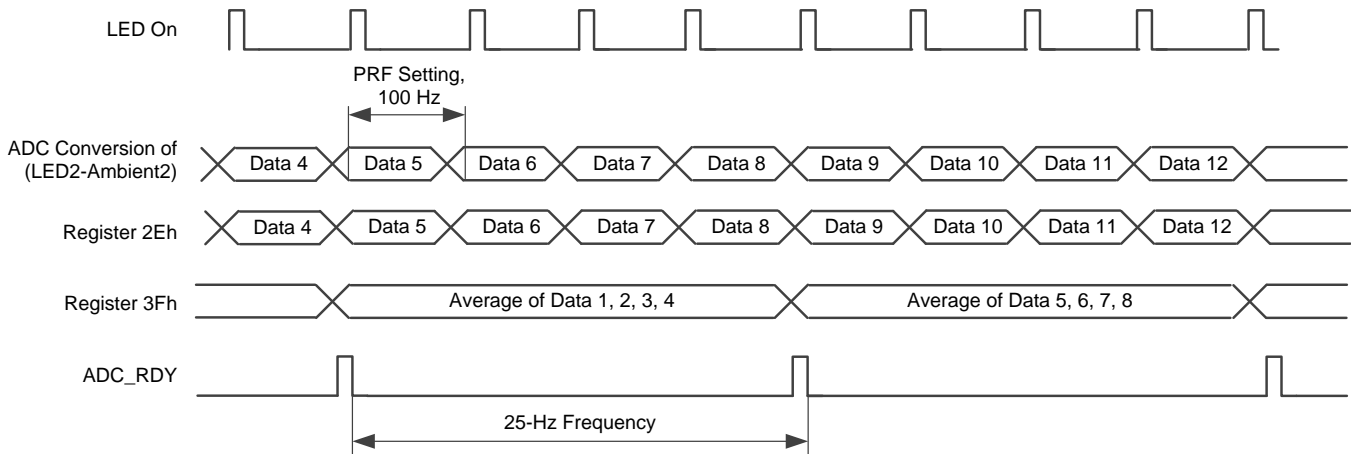
**Figure 37. Decimation Mode Enabled Timing Diagram
(Decimation Factor = 4, PRF = 100 Hz)**

8.4.6.1 Decimation Mode Power and Performance

The main advantage of the decimation mode is that this mode can be used to reduce the readout rate of the MCU because the data rate reduces by the decimation factor. Normally, reducing the data rate leads to SNR loss. However, with decimation mode, there is no SNR loss regardless of the lower data rate because of the averaging of consecutive samples. Table 15 compares different modes of operation.

Table 15. Different Modes of Operation

MODE	RATE OF DEVICE SAMPLES AND CONVERSIONS	RATE OF MCU DATA READS	RELATIVE PERFORMANCE
No decimation, 100-Hz PRF	100 Hz	100 Hz	Reference
No decimation, 25-Hz PRF	25 Hz	25 Hz	SNR is approximately 6 dB lower than reference
4X decimation mode, 100-Hz PRF	100 Hz	25 Hz	SNR is comparable to reference

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8.5 Register Map

Table 16. Register Map[1]

ADDRESS (Hex)	23	22	21	20	19	18	17	16	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
00h	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	SW_RESET	0	TM_COUNT_RST	REG_READ
01h	0	0	0	0	0	0	0	0	LED2STC															
02h	0	0	0	0	0	0	0	0	LED2ENDC															
03h	0	0	0	0	0	0	0	0	LED1LEDSTC															
04h	0	0	0	0	0	0	0	0	LED1LEDENDC															
05h	0	0	0	0	0	0	0	0	ALED2STC\LED3STC															
06h	0	0	0	0	0	0	0	0	ALED2ENDC\LED3ENDC															
07h	0	0	0	0	0	0	0	0	LED1STC															
08h	0	0	0	0	0	0	0	0	LED1ENDC															
09h	0	0	0	0	0	0	0	0	LED2LEDSTC															
0Ah	0	0	0	0	0	0	0	0	LED2LEDENDC															
0Bh	0	0	0	0	0	0	0	0	ALED1STC															
0Ch	0	0	0	0	0	0	0	0	ALED1ENDC															
0Dh	0	0	0	0	0	0	0	0	LED2CONVST															
0Eh	0	0	0	0	0	0	0	0	LED2CONVEND															
0Fh	0	0	0	0	0	0	0	0	ALED2CONVST\LED3CONVST															
10h	0	0	0	0	0	0	0	0	ALED2CONVEND\LED3CONVEND															
11h	0	0	0	0	0	0	0	0	LED1CONVST															
12h	0	0	0	0	0	0	0	0	LED1CONVEND															
13h	0	0	0	0	0	0	0	0	ALED1CONVST															
14h	0	0	0	0	0	0	0	0	ALED1CONVEND															
15h	0	0	0	0	0	0	0	0	ADCRSTSTCT0															
16h	0	0	0	0	0	0	0	0	ADCRSTENDCT0															
17h	0	0	0	0	0	0	0	0	ADCRSTSTCT1															
18h	0	0	0	0	0	0	0	0	ADCRSTENDCT1															
19h	0	0	0	0	0	0	0	0	ADCRSTSTCT2															
1Ah	0	0	0	0	0	0	0	0	ADCRSTENDCT2															
1Bh	0	0	0	0	0	0	0	0	ADCRSTSTCT3															
1Ch	0	0	0	0	0	0	0	0	ADCRSTENDCT3															
1Dh	0	0	0	0	0	0	0	0	PRPCT															

(1) After reset, all register bits are reset to 0.

Register Map (continued)

Table 16. Register Map[1] (continued)

ADDRESS (Hex)	23	22	21	20	19	18	17	16	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
1Eh	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	TIMEREN	0	0	0	0	NUMAV			
20h	0	0	0	0	0	0	0	0	ENSEPGAIN	0	0	0	0	0	0	0	0	0	TIA_CF_SEP			TIA_GAIN_SEP		
21h	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	PROG_TG_EN	0	0	TIA_CF			TIA_GAIN		
22h	0	0	0	0	0	0	ILED3						ILED2						ILED1					
23h	0	0	0	DYNAMIC1	0	0	ILED_2X	0	0	DYNAMIC2	0	0	0	0	OSC_ENABLE	0	0	0	0	DYNAMIC3	DYNAMIC4	0	PDNRX	PDNAFE
28h	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0
29h	0	0	0	0	0	0	0	0	0	0	0	0	0	0	ENABLE_CLKOUT	0	0	0	0	CLKDIV_CLKOUT				0
2Ah	LED2VAL																							
2Bh	ALED2VAL\LED3VAL																							
2Ch	LED1VAL																							
2Dh	ALED1VAL																							
2Eh	LED2-ALED2VAL[2]																							
2Fh	LED1-ALED1VAL																							
31h	0	0	0	0	0	0	0	0	0	0	0	0	PD_DISCONNECT	0	0	0	0	ENABLE_INPUT_SHORT	0	0	CLKDIV_EXTMODE			
32h	0	0	0	0	0	0	0	0	PDNCYCLESTC															

(2) Ignore the contents of this register when LED3 is used.

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Register Map (continued)

Table 16. Register Map[1] (continued)

ADDRESS (Hex)	23	22	21	20	19	18	17	16	15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0
33h	0	0	0	0	0	0	0	0	PDNCYCLEENDC															
34h	0	0	0	0	0	0	0	0	PROG_TG_STC															
35h	0	0	0	0	0	0	0	0	PROG_TG_ENDC															
36h	0	0	0	0	0	0	0	0	LED3LEDSTC															
37h	0	0	0	0	0	0	0	0	LED3LEDENDC															
39h	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	CLKDIV_PRF		
3Ah	0	0	0	0	POL_OFFDAC_LED2	I_OFFDAC_LED2				POL_OFFDAC_AMB1	I_OFFDAC_AMB1				POL_OFFDAC_LED1	I_OFFDAC_LED1				POL_OFFDAC_AMB2\POL_OFFDAC_LED3	I_OFFDAC_AMB2\I_OFFDAC_LED3			
3Dh	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	0	DEC_EN	0	DEC_FACTOR			0
3Fh	AVG_LED2-ALED2VAL																							
40h	AVG_LED1-ALED1VAL																							

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8.5.1 Register 0h (address = 0h) [reset = 0h]

Figure 38. Register 0h

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	14	13	12	11	10	9	8
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
7	6	5	4	3	2	1	0
0	0	0	0	SW_RESET	0	TM_COUNT_RST	REG_READ
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h

LEGEND: W = Write only; -n = value after reset

Table 17. Register 0h Field Descriptions

Bit	Field	Type	Reset	Description
23-4	0	W	0h	Must write 0.
3	SW_RESET	W	0h	Self-clearing reset bit. For a software reset, write 1.
2	0	W	0h	Must write 0.
1	TM_COUNT_RST	W	0h	Used to suspend the count and keep the counter in a reset state.
0	REG_READ	W	0h	Register readout enable for write registers (not needed for ADC output registers). 0 = Register write mode 1 = Enables the readout of write registers

8.5.2 Register 1h (address = 1h) [reset = 0h]

Figure 39. Register 1h

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	14	13	12	11	10	9	8
LED2STC							
R/W-0h							
7	6	5	4	3	2	1	0
LED2STC							
R/W-0h							

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 18. Register 1h Field Descriptions

Bit	Field	Type	Reset	Description
23-16	0	W	0h	Must write 0.
15-0	LED2STC	R/W	0h	Sample LED2 start

Product Folder Links: *AFE4404*

8.5.3 Register 2h (address = 2h) [reset = 0h]

Figure 40. Register 2h

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	14	13	12	11	10	9	8
LED2ENDC							
R/W-0h							
7	6	5	4	3	2	1	0
LED2ENDC							
R/W-0h							

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 19. Register 2h Field Descriptions

Bit	Field	Type	Reset	Description
23-16	0	W	0h	Must write 0.
15-0	LED2ENDC	R/W	0h	Sample LED2 end

8.5.4 Register 3h (address = 3h) [reset = 0h]

Figure 41. Register 3h

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	14	13	12	11	10	9	8
LED1LEDSTC							
R/W-0h							
7	6	5	4	3	2	1	0
LED1LEDSTC							
R/W-0h							

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 20. Register 3h Field Descriptions

Bit	Field	Type	Reset	Description
23-16	0	W	0h	Must write 0.
15-0	LED1LEDSTC	R/W	0h	LED1 start

8.5.5 Register 4h (address = 4h) [reset = 0h]

Figure 42. Register 4h

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	14	13	12	11	10	9	8
LED1LEDENDC							
R/W-0h							
7	6	5	4	3	2	1	0
LED1LEDENDC							
R/W-0h							

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 21. Register 4h Field Descriptions

Bit	Field	Type	Reset	Description
23-16	0	W	0h	Must write 0.
15-0	LED1LEDENDC	R/W	0h	LED1 end

8.5.6 Register 5h (address = 5h) [reset = 0h]

Figure 43. Register 5h

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	14	13	12	11	10	9	8
ALED2STC\LED3STC							
R/W-0h							
7	6	5	4	3	2	1	0
ALED2STC\LED3STC							
R/W-0h							

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 22. Register 5h Field Descriptions

Bit	Field	Type	Reset	Description
23-16	0	W	0h	Must write 0.
15-0	ALED2STC\LED3STC	R/W	0h	Sample ambient 2 (or sample LED3) start

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8.5.7 Register 6h (address = 6h) [reset = 0h]

Figure 44. Register 6h

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	14	13	12	11	10	9	8
ALED2ENDC\LED3ENDC							
R/W-0h							
7	6	5	4	3	2	1	0
ALED2ENDC\LED3ENDC							
R/W-0h							

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 23. Register 6h Field Descriptions

Bit	Field	Type	Reset	Description
23-16	0	W	0h	Must write 0.
15-0	ALED2ENDC\LED3ENDC	R/W	0h	Sample ambient 2 (or sample LED3) end

8.5.8 Register 7h (address = 7h) [reset = 0h]

Figure 45. Register 7h

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	14	13	12	11	10	9	8
LED1STC							
R/W-0h							
7	6	5	4	3	2	1	0
LED1STC							
R/W-0h							

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 24. Register 7h Field Descriptions

Bit	Field	Type	Reset	Description
23-16	0	W	0h	Must write 0.
15-0	LED1STC	R/W	0h	Sample LED1 start

8.5.9 Register 8h (address = 8h) [reset = 0h]

Figure 46. Register 8h

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	14	13	12	11	10	9	8
LED1ENDC							
R/W-0h							
7	6	5	4	3	2	1	0
LED1ENDC							
R/W-0h							

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 25. Register 8h Field Descriptions

Bit	Field	Type	Reset	Description
23-16	0	W	0h	Must write 0.
15-0	LED1ENDC	R/W	0h	Sample LED1 end

8.5.10 Register 9h (address = 9h) [reset = 0h]

Figure 47. Register 9h

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	14	13	12	11	10	9	8
LED2LEDSTC							
R/W-0h							
7	6	5	4	3	2	1	0
LED2LEDSTC							
R/W-0h							

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 26. Register 9h Field Descriptions

Bit	Field	Type	Reset	Description
23-16	0	W	0h	Must write 0.
15-0	LED2LEDSTC	R/W	0h	LED2 start

Product Folder Links: *AFE4404*

8.5.11 Register Ah (address = Ah) [reset = 0h]

Figure 48. Register Ah

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	14	13	12	11	10	9	8
LED2LEDENDC							
R/W-0h							
7	6	5	4	3	2	1	0
LED2LEDENDC							
R/W-0h							

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 27. Register Ah Field Descriptions

Bit	Field	Type	Reset	Description
23-16	0	W	0h	Must write 0.
15-0	LED2LEDENDC	R/W	0h	LED2 end

8.5.12 Register Bh (address = Bh) [reset = 0h]

Figure 49. Register Bh

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	14	13	12	11	10	9	8
ALED1STC							
R/W-0h							
7	6	5	4	3	2	1	0
ALED1STC							
R/W-0h							

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 28. Register Bh Field Descriptions

Bit	Field	Type	Reset	Description
23-16	0	W	0h	Must write 0.
15-0	ALED1STC	R/W	0h	Sample ambient 1 start

8.5.13 Register Ch (address = Ch) [reset = 0h]

Figure 50. Register Ch

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	14	13	12	11	10	9	8
ALED1ENDC							
R/W-0h							
7	6	5	4	3	2	1	0
ALED1ENDC							
R/W-0h							

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 29. Register Ch Field Descriptions

Bit	Field	Type	Reset	Description
23-16	0	W	0h	Must write 0.
15-0	ALED1ENDC	R/W	0h	Sample ambient 1 end

8.5.14 Register Dh (address = Dh) [reset = 0h]

Figure 51. Register Dh

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	14	13	12	11	10	9	8
LED2CONVST							
R/W-0h							
7	6	5	4	3	2	1	0
LED2CONVST							
R/W-0h							

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 30. Register Dh Field Descriptions

Bit	Field	Type	Reset	Description
23-16	0	W	0h	Must write 0.
15-0	LED2CONVST	R/W	0h	LED2 convert phase start

Product Folder Links: *AFE4404*

8.5.15 Register Eh (address = Eh) [reset = 0h]

Figure 52. Register Eh

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	14	13	12	11	10	9	8
LED2CONVEND							
R/W-0h							
7	6	5	4	3	2	1	0
LED2CONVEND							
R/W-0h							

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 31. Register Eh Field Descriptions

Bit	Field	Type	Reset	Description
23-16	0	W	0h	Must write 0.
15-0	LED2CONVEND	R/W	0h	LED2 convert phase end

8.5.16 Register Fh (address = Fh) [reset = 0h]

Figure 53. Register Fh

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	14	13	12	11	10	9	8
ALED2CONVST\LED3CONVST							
R/W-0h							
7	6	5	4	3	2	1	0
ALED2CONVST\LED3CONVST							
R/W-0h							

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 32. Register Fh Field Descriptions

Bit	Field	Type	Reset	Description
23-16	0	W	0h	Must write 0.
15-0	ALED2CONVST\LED3CONVST	R/W	0h	Ambient 2 (or LED3) convert phase start

Product Folder Links: *AFE4404*

8.5.17 Register 10h (address = 10h) [reset = 0h]

Figure 54. Register 10h

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	14	13	12	11	10	9	8
ALED2CONVEND\LED3CONVEND							
R/W-0h							
7	6	5	4	3	2	1	0
ALED2CONVEND\LED3CONVEND							
R/W-0h							

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 33. Register 10h Field Descriptions

Bit	Field	Type	Reset	Description
23-16	0	W	0h	Must write 0.
15-0	ALED2CONVEND\LED3CONVEND	R/W	0h	Ambient 2 (or LED3) convert phase end

8.5.18 Register 11h (address = 11h) [reset = 0h]

Figure 55. Register 11h

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	14	13	12	11	10	9	8
LED1CONVST							
R/W-0h							
7	6	5	4	3	2	1	0
LED1CONVST							
R/W-0h							

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 34. Register 11h Field Descriptions

Bit	Field	Type	Reset	Description
23-16	0	W	0h	Must write 0.
15-0	LED1CONVST	R/W	0h	LED1 convert phase start

8.5.19 Register 12h (address = 12h) [reset = 0h]

Figure 56. Register 12h

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	14	13	12	11	10	9	8
LED1CONVEND							
R/W-0h							
7	6	5	4	3	2	1	0
LED1CONVEND							
R/W-0h							

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 35. Register 12h Field Descriptions

Bit	Field	Type	Reset	Description
23-16	0	W	0h	Must write 0.
15-0	LED1CONVEND	R/W	0h	LED1 convert phase end

8.5.20 Register 13h (address = 13h) [reset = 0h]

Figure 57. Register 13h

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	14	13	12	11	10	9	8
ALED1CONVST							
R/W-0h							
7	6	5	4	3	2	1	0
ALED1CONVST							
R/W-0h							

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 36. Register 13h Field Descriptions

Bit	Field	Type	Reset	Description
23-16	0	W	0h	Must write 0
15-0	ALED1CONVST	R/W	0h	Ambient 1 convert phase start

8.5.21 Register 14h (address = 14h) [reset = 0h]

Figure 58. Register 14h

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	**14**	**13**	**12**	**11**	**10**	**9**	**8**
ALED1CONVEND							
R/W-0h							
7	**6**	**5**	**4**	**3**	**2**	**1**	**0**
ALED1CONVEND							
R/W-0h							

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 37. Register 14h Field Descriptions

Bit	Field	Type	Reset	Description
23-16	0	W	0h	Must write 0.
15-0	ALED1CONVEND	R/W	0h	Ambient 1 convert phase end

8.5.22 Register 15h (address = 15h) [reset = 0h]

Figure 59. Register 15h

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	**14**	**13**	**12**	**11**	**10**	**9**	**8**
ADCRSTSTCT0							
R/W-0h							
7	**6**	**5**	**4**	**3**	**2**	**1**	**0**
ADCRSTSTCT0							
R/W-0h							

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 38. Register 15h Field Descriptions

Bit	Field	Type	Reset	Description
23-16	0	W	0h	Must write 0.
15-0	ADCRSTSTCT0	R/W	0h	ADC reset phase 0 start

8.5.23   Register 16h (address = 16h) [reset = 0h]

Figure 60. Register 16h

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	14	13	12	11	10	9	8
ADCRSTENDCT0							
R/W-0h							
7	6	5	4	3	2	1	0
ADCRSTENDCT0							
R/W-0h							

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 39. Register 16h Field Descriptions

Bit	Field	Type	Reset	Description
23-16	0	W	0h	Must write 0.
15-0	ADCRSTENDCT0	R/W	0h	ADC reset phase 0 end

8.5.24   Register 17h (address = 17h) [reset = 0h]

Figure 61. Register 17h

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	14	13	12	11	10	9	8
ADCRSTSTCT1							
R/W-0h							
7	6	5	4	3	2	1	0
ADCRSTSTCT1							
R/W-0h							

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 40. Register 17h Field Descriptions

Bit	Field	Type	Reset	Description
23-16	0	W	0h	Must write 0.
15-0	ADCRSTSTCT1	R/W	0h	ADC reset phase 1 start

8.5.25 Register 18h (address = 18h) [reset = 0h]

Figure 62. Register 18h

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	14	13	12	11	10	9	8
ADCRSTENDCT1							
R/W-0h							
7	6	5	4	3	2	1	0
ADCRSTENDCT1							
R/W-0h							

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 41. Register 18h Field Descriptions

Bit	Field	Type	Reset	Description
23-16	0	W	0h	Must write 0.
15-0	ADCRSTENDCT1	R/W	0h	ADC reset phase 1 end

8.5.26 Register 19h (address = 19h) [reset = 0h]

Figure 63. Register 19h

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	14	13	12	11	10	9	8
ADCRSTSTCT2							
R/W-0h							
7	6	5	4	3	2	1	0
ADCRSTSTCT2							
R/W-0h							

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 42. Register 19h Field Descriptions

Bit	Field	Type	Reset	Description
23-16	0	W	0h	Must write 0.
15-0	ADCRSTSTCT2	R/W	0h	ADC reset phase 2 start

Product Folder Links: *AFE4404*

8.5.27 Register 1Ah (address = 1Ah) [reset = 0h]

Figure 64. Register 1Ah

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	**14**	**13**	**12**	**11**	**10**	**9**	**8**
ADCRSTENDCT2							
R/W-0h							
7	**6**	**5**	**4**	**3**	**2**	**1**	**0**
ADCRSTENDCT2							
R/W-0h							

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 43. Register 1Ah Field Descriptions

Bit	Field	Type	Reset	Description
23-16	0	W	0h	Must write 0.
15-0	ADCRSTENDCT2	R/W	0h	ADC reset phase 2 end

8.5.28 Register 1Bh (address = 1Bh) [reset = 0h]

Figure 65. Register 1Bh

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	**14**	**13**	**12**	**11**	**10**	**9**	**8**
ADCRSTSTCT3							
R/W-0h							
7	**6**	**5**	**4**	**3**	**2**	**1**	**0**
ADCRSTSTCT3							
R/W-0h							

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 44. Register 1Bh Field Descriptions

Bit	Field	Type	Reset	Description
23-16	0	W	0h	Must write 0.
15-0	ADCRSTSTCT3	R/W	0h	ADC reset phase 3 start

8.5.29 Register 1Ch (address = 1Ch) [reset = 0h]

Figure 66. Register 1Ch

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	14	13	12	11	10	9	8
ADCRSTENDCT3							
R/W-0h							
7	6	5	4	3	2	1	0
ADCRSTENDCT3							
R/W-0h							

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 45. Register 1Ch Field Descriptions

Bit	Field	Type	Reset	Description
23-16	0	W	0h	Must write 0.
15-0	ADCRSTENDCT3	R/W	0h	ADC reset phase 3 end

8.5.30 Register 1Dh (address = 1Dh) [reset = 0h]

Figure 67. Register 1Dh

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	14	13	12	11	10	9	8
PRPCT							
R/W-0h							
7	6	5	4	3	2	1	0
PRPCT							
R/W-0h							

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 46. Register 1Dh Field Descriptions

Bit	Field	Type	Reset	Description
23-16	0	W	0h	Must write 0.
15-0	PRPCT	R/W	0h	These bits are the count value for the counter that sets the PRF. The counter automatically counts until PRPCT and then returns back to 0 to start the next count.

8.5.31 Register 1Eh (address = 1Eh) [reset = 0h]

Figure 68. Register 1Eh

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	**14**	**13**	**12**	**11**	**10**	**9**	**8**
0	0	0	0	0	0	0	TIMEREN
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	R/W-0h
7	**6**	**5**	**4**	**3**	**2**	**1**	**0**
0	0	0	0	NUMAV			
W-0h	W-0h	W-0h	W-0h	R/W-0h			

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 47. Register 1Eh Field Descriptions

Bit	Field	Type	Reset	Description
23-9	0	W	0h	Must write 0.
8	TIMEREN	R/W	0h	0 = Timer module disabled 1 = Enables timer module. This bit enables the timing engine that can be programmed to generate all clock phases for the synchronized transmit drive, receive sampling, and data conversion.
7-4	0	W	0h	Must write 0.
3-0	NUMAV	R/W	0h	These bits determine the number of ADC averages. By programming a higher ADC conversion time, the ADC can be set to do multiple conversions and average these multiple conversions to achieve lower noise. This programmability is set with the NUMAV bit control. The number of samples that are averaged is represented by the decimal equivalent of NUMAV + 1. For example, NUMAV = 0 represents no averaging, NUMAV = 2 represents averaging of three samples, and NUMAV = 15 represents averaging of 16 samples.

8.5.32 Register 20h (address = 20h) [reset = 0h]

Figure 69. Register 20h

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	**14**	**13**	**12**	**11**	**10**	**9**	**8**
ENSEPGAIN	0	0	0	0	0	0	0
R/W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
7	**6**	**5**	**4**	**3**	**2**	**1**	**0**
0	0	TIA_CF_SEP			TIA_GAIN_SEP		
W-0h	W-0h	R/W-0h			R/W-0h		

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 48. Register 20h Field Descriptions

Bit	Field	Type	Reset	Description
23-16	0	W	0h	Must write 0.
15	ENSEPGAIN	R/W	0h	0 = Single TIA gain for all phases 1 = Enables two separate sets of TIA gains
14-6	0	W	0h	Must write 0.
5-3	TIA_CF_SEP	R/W	0h	When ENSEPGAIN = 1, TIA_CF_SEP is the control for the C_{f2} setting.
2-0	TIA_GAIN_SEP	R/W	0h	When ENSEPGAIN = 1, TIA_GAIN_SEP is the control for the R_{f2} setting.

Product Folder Links: *AFE4404*

8.5.33 Register 21h (address = 21h) [reset = 0h]

Figure 70. Register 21h

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	14	13	12	11	10	9	8
0	0	0	0	0	0	0	PROG_TG_EN
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
7	6	5	4	3	2	1	0
0	0		TIA_CF			TIA_GAIN	
W-0h	W-0h		R/W-0h			R/W-0h	

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 49. Register 21h Field Descriptions

Bit	Field	Type	Reset	Description
23-9	0	W	0h	Must write 0.
8	PROG_TG_EN	W	0h	This bit replaces the ADC_RDY output with a fully-programmable signal from the timing engine. The start and end points of this signal are set using the PROG_TG_STC and PROG_TG_ENDC controls.
7-6	0	W	0h	Must write 0.
5-3	TIA_CF	R/W	0h	When ENSEPGAIN = 0, these bits control the C_f setting (both C_{f1} and C_{f2}); see Table 51 for details. When ENSEPGAIN = 1, these bits control the C_{f1} setting.
2-0	TIA_GAIN	R/W	0h	When ENSEPGAIN = 0, these bits control the R_f setting (both R_{f1} and R_{f2}); see Table 50 for details. When ENSEPGAIN = 1, these bits control the R_{f1} setting.

Table 50. TIA_GAIN Register Settings

TIA_GAIN, TIA_GAIN_SEP REGISTER VALUE	R_f
0	500 kΩ
1	250 kΩ
2	100 kΩ
3	50 kΩ
4	25 kΩ
5	10 kΩ
6	1 MΩ
7	2 MΩ

Table 51. TIA_CF Register Settings

TIA_CF, TIA_CF_SEP REGISTER VALUE	C_f
0	5 pF
1	2.5 pF
2	10 pF
3	7.5 pF
4	20 pF
5	17.5 pF
6	25 pF
7	22.5 pF

8.5.34 Register 22h (address = 22h) [reset = 0h]

Figure 71. Register 22h

23	22	21	20	19	18	17	16
0	0	0	0	0	0	ILED3	
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	R/W-0h	
15	**14**	**13**	**12**	**11**	**10**	**9**	**8**
ILED3				ILED2			
R/W-0h				R/W-0h			
7	**6**	**5**	**4**	**3**	**2**	**1**	**0**
ILED2		ILED1					
R/W-0h		R/W-0h					

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 52. Register 22h Field Descriptions

Bit	Field	Type	Reset	Description
23-18	0	W	0h	Must write 0.
17-12	ILED3	R/W	0h	LED3 current control
11-6	ILED2	R/W	0h	LED2 current control
5-0	ILED1	R/W	0h	LED1 current control. Increments of the LED1 current setting are listed in Table 53.

Table 53. ILED1 Register Settings

ILED1, ILED2, ILED3 REGISTER VALUES	LED CURRENT SETTING (mA)
0	0
1	0.8
2	1.6
3	2.4
…	…
63	50

Product Folder Links: *AFE4404*

8.5.35 Register 23h (address = 23h) [reset = 0h]

Figure 72. Register 23h

23	22	21	20	19	18	17	16
0	0	0	DYNAMIC1	0	0	ILED_2X	0
W-0h	W-0h	W-0h	R/W-0h	W-0h	W-0h	R/W-0h	W-0h
15	14	13	12	11	10	9	8
0	DYNAMIC2	0	0	0	0	OSC_ENABLE	0
W-0h	R/W-0h	W-0h	W-0h	W-0h	W-0h	R/W-0h	W-0h
7	6	5	4	3	2	1	0
0	0	0	DYNAMIC3	DYNAMIC4	0	PDNRX	PDNAFE
W-0h	W-0h	W-0h	R/W-0h	R/W-0h	W-0h	R/W-0h	R/W-0h

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 54. Register 23h Field Descriptions

Bit	Field	Type	Reset	Description
23-21	0	W	0h	Must write 0.
20	DYNAMIC1	R/W	0h	0 = Transmitter is not powered down 1 = Transmitter is powered down in dynamic power-down mode
19-18	0	W	0h	Must write 0.
17	ILED_2X	R/W	0h	0 = LED current range is 0 mA to 50 mA 1 = LED current range is 0 mA to 100 mA
16-15	0	W	0h	Must write 0.
14	DYNAMIC2	R/W	0h	0 = ADC is not powered down 1 = ADC is powered down in dynamic power-down mode
13-10	0	W	0h	Must write 0.
9	OSC_ENABLE	R/W	0h	0 = External clock mode (default). In this mode, the CLK pin functions as an input pin where the external clock can be input. 1 = Enables oscillator mode. In this mode, the 4-MHz internal oscillator is enabled.
8-5	0	W	0h	Must write 0.
4	DYNAMIC3	R/W	0h	0 = TIA is not powered down 1 = TIA is powered down in dynamic power-down mode
3	DYNAMIC4	R/W	0h	0 = Rest of ADC is not powered down 1 = Rest of ADC is powered down in dynamic power-down mode
2	0	W	0h	Must write 0.
1	PDNRX	R/W	0h	0 = Normal mode 1 = RX portion of the AFE is powered down
0	PDNAFE	R/W	0h	0 = Normal mode 1 = Entire AFE is powered down

8.5.36 Register 29h (address = 29h) [reset = 0h]

Figure 73. Register 29h

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	14	13	12	11	10	9	8
0	0	0	0	0	0	ENABLE_CLKOUT	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	R/W-0h	W-0h
7	6	5	4	3	2	1	0
0	0	0	CLKDIV_CLKOUT				0
W-0h	W-0h	W-0h	R/W-0h				W-0h

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 55. Register 29h Field Descriptions

Bit	Field	Type	Reset	Description
23-10	0	W	0h	Must write 0.
9	ENABLE_CLKOUT	R/W	0h	In internal clock mode, the internally-generated clock can be output on the CLK pin. 0 = Disables the clock output 1 = Enables CLKOUT generation and buffering on the CLK pin. The frequency of the clock output on the CLK pin (in internal clock mode) can be set using a programmable divider controlled by the CLKDIV_CLKOUT register bit.
8-5	0	W	0h	Must write 0.
4-1	CLKDIV_CLKOUT	R/W	0h	Set the frequency of the clock output on the CLK pin (in the internal clock mode), as shown in Table 56.

Table 56. CLKDIV_CLKOUT Register Settings

CLKDIV_CLKOUT REGISTER SETTINGS	DIVISION RATIO	FREQUENCY OF OUTPUT CLOCK IN MHz
0	1	4
1	2	2
2	4	1
3	8	0.5
4	16	0.25
5	32	0.125
6	64	0.0625
7	128	0.03125
8..15	Do not use	Do not use

8.5.37 Register 2Ah (address = 2Ah) [reset = 0h]

Figure 74. Register 2Ah

23	22	21	20	19	18	17	16
LED2VAL							
R-0h							
15	14	13	12	11	10	9	8
LED2VAL							
R-0h							
7	6	5	4	3	2	1	0
LED2VAL							
R-0h							

LEGEND: R = Read only; -n = value after reset

Table 57. Register 2Ah Field Descriptions

Bit	Field	Type	Reset	Description
23-0	LED2VAL	R	0h	These bits are the LED2 output code in 24-bit, twos complement format.

8.5.38 Register 2Bh (address = 2Bh) [reset = 0h]

Figure 75. Register 2Bh

23	22	21	20	19	18	17	16
ALED2VAL\LED3VAL							
R-0h							
15	14	13	12	11	10	9	8
ALED2VAL\LED3VAL							
R-0h							
7	6	5	4	3	2	1	0
ALED2VAL\LED3VAL							
R-0h							

LEGEND: R = Read only; -n = value after reset

Table 58. Register 2Bh Field Descriptions

Bit	Field	Type	Reset	Description
23-0	ALED2VAL\LED3VAL	R	0h	These bits are the ambient 2 or LED3 output code in 24-bit, twos complement format.

8.5.39 Register 2Ch (address = 2Ch) [reset = 0h]

Figure 76. Register 2Ch

23	22	21	20	19	18	17	16
			LED1VAL				
			R-0h				
15	14	13	12	11	10	9	8
			LED1VAL				
			R-0h				
7	6	5	4	3	2	1	0
			LED1VAL				
			R-0h				

LEGEND: R = Read only; -n = value after reset

Table 59. Register 2Ch Field Descriptions

Bit	Field	Type	Reset	Description
23-0	LED1VAL	R	0h	These bits are the LED1 output code in 24-bit, twos complement format.

8.5.40 Register 2Dh (address = 2Dh) [reset = 0h]

Figure 77. Register 2Dh

23	22	21	20	19	18	17	16
			ALED1VAL				
			R-0h				
15	14	13	12	11	10	9	8
			ALED1VAL				
			R-0h				
7	6	5	4	3	2	1	0
			ALED1VAL				
			R-0h				

LEGEND: R = Read only; -n = value after reset

Table 60. Register 2Dh Field Descriptions

Bit	Field	Type	Reset	Description
23-0	ALED1VAL	R	0h	These bits are the ambient 1 output code in 24-bit, twos complement format.

8.5.41 Register 2Eh (address = 2Eh) [reset = 0h]

Figure 78. Register 2Eh

23	22	21	20	19	18	17	16
LED2-ALED2VAL
R-0h
15	14	13	12	11	10	9	8
LED2-ALED2VAL
R-0h
7	6	5	4	3	2	1	0
LED2-ALED2VAL
R-0h

LEGEND: R = Read only; -n = value after reset

Table 61. Register 2Eh Field Descriptions

Bit	Field	Type	Reset	Description
23-0	LED2-ALED2VAL[1]	R	0h	These bits are the LED2-ambient2 output code in 24-bit, twos complement format.

(1) Ignore the content of this register when LED3 is used.

8.5.42 Register 2Fh (address = 2Fh) [reset = 0h]

Figure 79. Register 2Fh

23	22	21	20	19	18	17	16
LED1-ALED1VAL
R-0h
15	14	13	12	11	10	9	8
LED1-ALED1VAL
R-0h
7	6	5	4	3	2	1	0
LED1-ALED1VAL
R-0h

LEGEND: R = Read only; -n = value after reset

Table 62. Register 2Fh Field Descriptions

Bit	Field	Type	Reset	Description
23-0	LED1-ALED1VAL	R	0h	These bits are the LED1-ambient1 output code in 24-bit, twos complement format.

8.5.43 Register 31h (address = 31h) [reset = 0h]

Figure 80. Register 31h

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	14	13	12	11	10	9	8
0	0	0	0	0	PD_DISCONNECT	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
7	6	5	4	3	2	1	0
0	0	ENABLE_INPUT_SHORT	0	0	CLKDIV_EXTMODE		
W-0h	W-0h	R/W-0h			R/W-0h		

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 63. Register 31h Field Descriptions

Bit	Field	Type	Reset	Description
23-11	0	W	0h	Must write 0.
10	PD_DISCONNECT	W	0h	This bit disconnects the PD signals (INP, INM) from the TIA inputs. When enabled, the current input to the TIA is determined completely by the offset cancellation DAC current (I_OFFDAC). Note that in this mode, the AFE no longer sets the bias for the PD.
9-6	0	W	0h	Must write 0.
5	ENABLE_INPUT_SHORT	R/W	0h	INP, INN are shorted to VCM whenever the TIA is in power-down.
4-3	0	W	0h	Must write 0.
2-0	CLKDIV_EXTMODE	R/W	0h	These bits are used to set the division ratio to allow flexible clocking in external clock mode. For details, see Table 64.

Table 64. CLKDIV_EXTMODE Register Settings

CLKDIV_EXTMODE REGISTER SETTINGS	DIVISION RATIO	ALLOWED FREQUENCY RANGE OF EXTERNAL CLOCK IN MHz
0	2	8-12
1	8	32-48
2	Do not use	Do not use
3	12	48-60
4	4	16-24
5	1	4-6
6	6	24-36
7	Do not use	Do not use

8.5.44 Register 32h (address = 32h) [reset = 0h]

Figure 81. Register 32h

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	14	13	12	11	10	9	8
PDNCYCLESTC							
R/W-0h							
7	6	5	4	3	2	1	0
PDNCYCLESTC							
R/W-0h							

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 65. Register 32h Field Descriptions

Bit	Field	Type	Reset	Description
23-16	0	W	0h	Must write 0.
15-0	PDNCYCLESTC	R/W	0h	PDN_CYCLE start

8.5.45 Register 33h (address = 33h) [reset = 0h]

Figure 82. Register 33h

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	14	13	12	11	10	9	8
PDNCYCLEENDC							
R/W-0h							
7	6	5	4	3	2	1	0
PDNCYCLEENDC							
R/W-0h							

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 66. Register 33h Field Descriptions

Bit	Field	Type	Reset	Description
23-16	0	W	0h	Must write 0.
15-0	PDNCYCLEENDC	R/W	0h	PDN_CYCLE end

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8.5.46 Register 34h (address = 34h) [reset = 0h]

Figure 83. Register 34h

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	14	13	12	11	10	9	8
PROG_TG_STC							
W-0h							
7	6	5	4	3	2	1	0
PROG_TG_STC							
W-0h							

LEGEND: W = Write only; -n = value after reset

Table 67. Register 34h Field Descriptions

Bit	Field	Type	Reset	Description
23-16	0	W	0h	Must write 0.
15-0	PROG_TG_STC	W	0h	These bits define the start time for the programmable timing engine signal that can replace ADC_RDY.

8.5.47 Register 35h (address = 35h) [reset = 0h]

Figure 84. Register 35h

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	14	13	12	11	10	9	8
PROG_TG_ENDC							
W-0h							
7	6	5	4	3	2	1	0
PROG_TG_ENDC							
W-0h							

LEGEND: W = Write only; -n = value after reset

Table 68. Register 35h Field Descriptions

Bit	Field	Type	Reset	Description
23-16	0	W	0h	Must write 0.
15-0	PROG_TG_ENDC	W	0h	These bits define the end time for the programmable timing engine signal that can replace ADC_RDY.

8.5.48 Register 36h (address = 36h) [reset = 0h]

Figure 85. Register 36h

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	14	13	12	11	10	9	8
LED3LEDSTC							
R/W-0h							
7	6	5	4	3	2	1	0
LED3LEDSTC							
R/W-0h							

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 69. Register 36h Field Descriptions

Bit	Field	Type	Reset	Description
23-16	0	W	0h	Must write 0.
15-0	LED3LEDSTC	R/W	0h	LED3 start. If LED3 is not used, set these register bits to '0'.

8.5.49 Register 37h (address = 37h) [reset = 0h]

Figure 86. Register 37h

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	14	13	12	11	10	9	8
LED3LEDENDC							
R/W-0h							
7	6	5	4	3	2	1	0
LED3LEDENDC							
R/W-0h							

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 70. Register 37h Field Descriptions

Bit	Field	Type	Reset	Description
23-16	0	W	0h	Must write 0.
15-0	LED3LEDENDC	R/W	0h	LED3 end. If LED3 is not used, set these register bits to '0'.

8.5.50 Register 39h (address = 39h) [reset = 0h]

Figure 87. Register 39h

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	**14**	**13**	**12**	**11**	**10**	**9**	**8**
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
7	**6**	**5**	**4**	**3**	**2**	**1**	**0**
0	0	0	0	0	CLKDIV_PRF		
W-0h	W-0h	W-0h	W-0h	W-0h	R/W-0h		

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 71. Register 39h Field Descriptions

Bit	Field	Type	Reset	Description
23-3	0	W	0h	Must write 0.
2-0	CLKDIV_PRF	R/W	0h	Clock division ratio for the clock to the timing engine. For details, see Table 72.

Table 72. CLKDIV_PRF Register Settings

CLKDIV_PRF REGISTER SETTINGS	DIVISION RATIO	FREQUENCY OF THE TIMING CLOCK in MHz (When the ADC Clock is 4 MHz)	LOWEST PRF SETTING (In Hz[1])
0	1	4	61
1	Do not use	Do not use	Do not use
2	Do not use	Do not use	Do not use
3	Do not use	Do not use	Do not use
4	2	2	31
5	4	1	15
6	8	0.5	8
7	16	0.25	4

(1) Limit to 10 Hz.

8.5.51 Register 3Ah (address = 3Ah) [reset = 0h]

Figure 88. Register 3Ah

23	22	21	20	19	18	17	16
0	0	0	0	POL_OFFDAC_LED2	I_OFFDAC_LED2		
W-0h	W-0h	W-0h	W-0h	R/W-0h	R/W-0h		

15	14	13	12	11	10	9	8
I_OFFDAC_LED2	POL_OFFDAC_AMB1	I_OFFDAC_AMB1				POL_OFFDAC_LED1	I_OFFDAC_LED1
R/W-0h	R/W-0h	R/W-0h				R/W-0h	R/W-0h

7	6	5	4	3	2	1	0
I_OFFDAC_LED1			POL_OFFDAC_AMB2\POL_OFFDAC_LED3	I_OFFDAC_AMB2\I_OFFDAC_LED3			
R/W-0h			R/W-0h	R/W-0h			

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 73. Register 3Ah Field Descriptions

Bit	Field	Type	Reset	Description
23-20	0	W	0h	Must write 0.
19	POL_OFFDAC_LED2	R/W	0h	Offset cancellation DAC polarity for LED2
18-15	I_OFFDAC_LED2	R/W	0h	Offset cancellation DAC setting forLED2
14	POL_OFFDAC_AMB1	R/W	0h	Offset cancellation DAC polarity for ambient 1
13-10	I_OFFDAC_AMB1	R/W	0h	Offset cancellation DAC setting for ambient 1
9	POL_OFFDAC_LED1	R/W	0h	Offset cancellation DAC polarity for LED1
8-5	I_OFFDAC_LED1	R/W	0h	Offset cancellation DAC setting for LED1, as described in Table 74.
4	POL_OFFDAC_AMB2\POL_OFFDAC_LED3	R/W	0h	Offset cancellation DAC polarity for ambient 2 (or LED3)
3-0	I_OFFDAC_AMB2\I_OFFDAC_LED3	R/W	0h	Offset cancellation DAC setting for ambient 2 (or LED3)

Table 74. I_OFFDAC Register Settings[1][2]

I_OFFDAC REGISTER SETTINGS	OFFSET CANCELLATION DAC CURRENT (µA) WITH POL_OFFDAC = 0	OFFSET CANCELLATION DAC CURRENT (µA) WITH POL_OFFDAC = 1
0	0	0
1	0.47	−0.47
2	0.93	−0.93
3	1.4	−1.4
4	1.87	−1.87
5	2.33	−2.33
6	2.8	−2.8
7	3.27	−3.27
8	3.73	−3.73
9	4.2	−4.2
10	4.67	−4.67
11	5.13	−5.13
12	5.6	−5.6
13	6.07	−6.07
14	6.53	−6.53
15	7	−7

(1) I_OFFDAC can correspond to one of the four phases. POL_OFFDAC corresponds to the polarity control for the same phase.
(2) The offset cancellation DAC is not trimmed at production and, therefore, the value of the full-scale current can vary across units by ±20%.

8.5.52 Register 3Dh (address = 3Dh) [reset = 0h]

Figure 89. Register 3Dh

23	22	21	20	19	18	17	16
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
15	14	13	12	11	10	9	8
0	0	0	0	0	0	0	0
W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h	W-0h
7	6	5	4	3	2	1	0
0	0	DEC_EN	0	DEC_FACTOR			0
W-0h	W-0h	R/W-0h	W-0h	R/W-0h			W-0h

LEGEND: R/W = Read/Write; W = Write only; -n = value after reset

Table 75. Register 3Dh Field Descriptions

Bit	Field	Type	Reset	Description
23-6	0	W	0h	Must write 0.
5	DEC_EN	R/W	0h	0 = Decimation mode disabled 1 = Decimation mode enabled
4	0	W	0h	Must write 0.
3-1	DEC_FACTOR	R/W	0h	Decimation factor (how many samples are to be averaged); see Table 76 for details.
0	0	W	0h	Must write 0.

Table 76. DEC_FACTOR Register Settings

DEC_FACTOR REGISTER SETTINGS	DECIMATION FACTOR
0	1
1	2
2	4
3	8
4	16
5-8	Do not use

Product Folder Links: *AFE4404*

8.5.53 Register 3Fh (address = 3Fh) [reset = 0h]

Figure 90. Register 3Fh

23	22	21	20	19	18	17	16
AVG_LED2-ALED2VAL							
R-0h							
15	14	13	12	11	10	9	8
AVG_LED2-ALED2VAL							
R-0h							
7	6	5	4	3	2	1	0
AVG_LED2-ALED2VAL							
R-0h							

LEGEND: R = Read only; -n = value after reset

Table 77. Register 3Fh Field Descriptions

Bit	Field	Type	Reset	Description
23-0	AVG_LED2-ALED2VAL	R	0h	These bits are the 24-bit averaged output code for (LED2-Ambient2) when decimation mode is enabled. The averaging is done over the number of samples specified by the decimation factor.

8.5.54 Register 40h (address = 40h) [reset = 0h]

Figure 91. Register 40h

23	22	21	20	19	18	17	16
AVG_LED1-ALED1VAL							
R-0h							
15	14	13	12	11	10	9	8
AVG_LED1-ALED1VAL							
R-0h							
7	6	5	4	3	2	1	0
AVG_LED1-ALED1VAL							
R-0h							

LEGEND: R = Read only; -n = value after reset

Table 78. Register 40h Field Descriptions

Bit	Field	Type	Reset	Description
23-0	AVG_LED1-ALED1VAL	R	0h	These bits are the 24-bit averaged output code for (LED1-Ambient1) when decimation mode is enabled. The averaging is done over the number of samples specified by the decimation factor.

9 Application and Implementation

> **NOTE**
> Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

9.1 Application Information

The AFE is designed to operate with a minimal number of external components. Deriving the power supplies for the AFE from the available source of power in the system can require an additional external LDO or boost converter. A reset is essential after power-up to ensure that all registers are reset to their default values. TI also recommends that the entire system be operated using a single master clock. The AFE can either be set to accept an external clock derived from a master clock generated elsewhere in the system, or the AFE can provide its internal oscillator as an output clock to serve as the master clock for the rest of the system. If a single master clock is not possible, extra care must be taken to ensure that spurious energy from unrelated clocks does not get coupled into the AFE. If this energy does couple into the AFE the spurs get aliased based on the sampling operation. These aliased spurs can result in a faulty detection of parameters (such as heart rate). The photodiode outputs are specifically prone to picking up noise. Especially when operating in coexistence and close proximity with RF communication circuitry [such as Bluetooth® low energy (BLE)], a common-mode choke may become essential to add in the path of the AFE inputs to reject the interference.

9.2 Typical Application
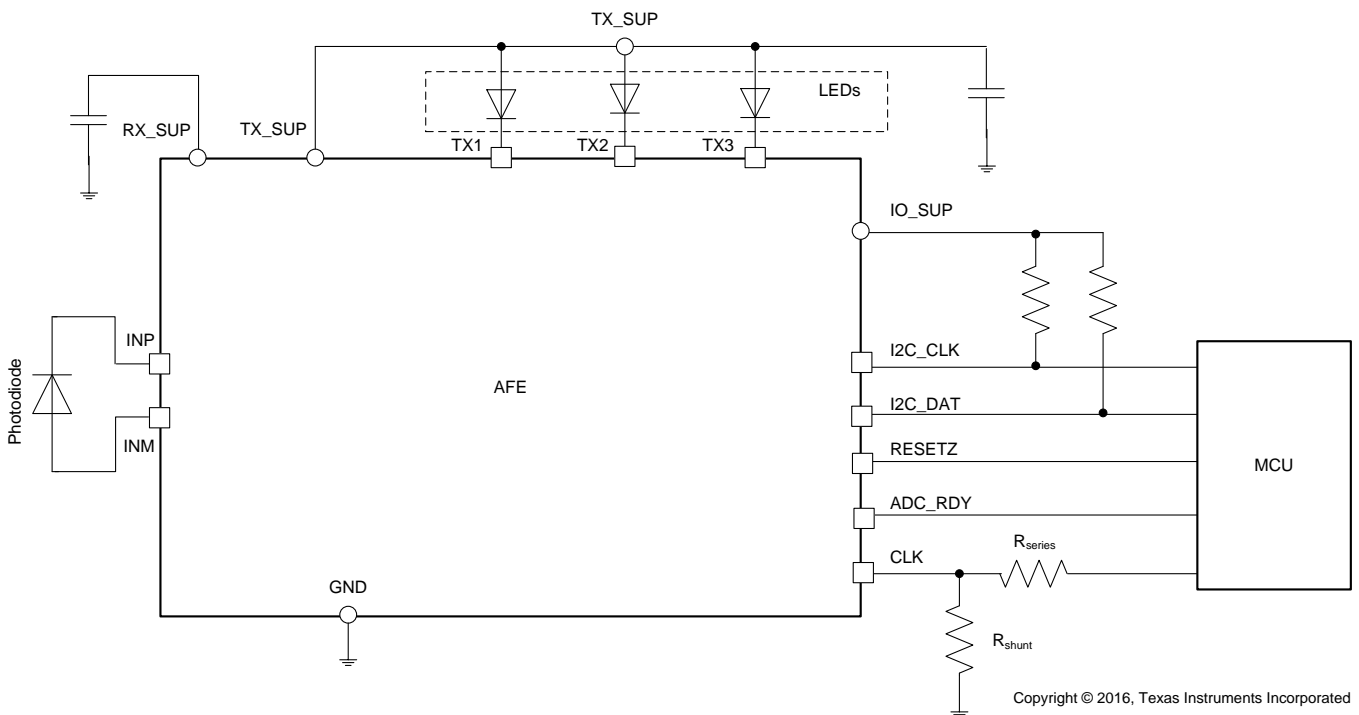
NOTE: Use R_{series} in external clock mode and R_{shunt} in internal oscillator mode.

Figure 92. Typical AFE Connection

Product Folder Links: *AFE4404*

Typical Application (continued)

Figure 92 illustrates the typical connection of the AFE. The following points are to be noted:

1. Use decoupling capacitors (1 µF or higher) placed close to the device to filter noise on RX_SUP and TX_SUP.
2. The voltage level used for IO_SUP must be the same as the I/O voltage level for the MCU.
3. In external clock mode, TI recommends connecting a series resistor (R_{series}) on the CLK pin. At power-up and before a RESET pulse is applied, the register bits can be in an uninitialized state. The CLK pin can possibly be configured as an output pin in this uninitialized state because the CLK pin is an I/O pin. In such a scenario, R_{series} limits the current (because the MCU also attempts to drive the CLK pin). For maximum frequency of the external clock (60 MHz), the R_{series} value is recommended to be 500 Ω.
4. In internal oscillator mode, a shunt resistor (R_{shunt}) equal to 500 kΩ is recommended to be connected to the CLK pin. At power-up and after reset, the device resets to the default mode of the external clock. The CLK pin is in a tri-state mode until the internal clock mode with the CLK output enabled is written through the I^{2}C interface. The function of R_{shunt} is to pull down the CLK pin to a logic level of 0 so that the input clock to the MCU is at a logic level even when the CLK pin is tri-stated.
5. When in power-down mode (PWDN and PDNAFE) the CLK pin must be shut off (tri-stated or driven to zero), if externally driven.

9.2.1 Design Requirements

The AFE architecture is very flexible, and can be used for both high-performance saturation of peripheral capillary oxygen (SpO2) applications as well as low-power, battery-operated heart-rate monitoring (HRM) applications as a result of this flexibility. The high dynamic range of the AFE enables excellent SNR for the signal of interest (usually small in amplitude) even in the presence of large-signal artifacts resulting from ambient and motion changes.

9.2.2 Detailed Design Procedure

The following important factors are key to extracting the full performance benefit from the AFE:

1. Good optics including bright LEDs and high-sensitivity photodiodes
2. Good mechanical design
3. A calibration loop that sets the optimal AFE settings based on the signal conditions

TI recommends that a system-level budgeting of dynamic range be initially done based on the following factors:

1. The range of the dc signal currents that are input to the AFE
2. The range of ac-to-dc ratio across different users
3. Signal current changes expected from artifacts (such as motion and ambient light changes)
4. The SNR required for heart-rate extraction algorithms to function successfully

Based on the above analysis, the available dynamic range from the AFE (approximately 100 dB) can be partitioned between the various components, and the target dc level for the calibration algorithm can also be arrived at.

9.2.2.1 System-Level ESD Considerations

To meet system-level ESD requirements, additional on-board ESD protection diodes may be required to be connected to the AFE4404 input pins. The input pins are sensitive to leakage, so using low-leakage ESD diodes is recommended for protecting these pins.

TI's portfolio of ESD protection devices can be accessed at the Overview for ESD Protection Diodes page.

The *ESD Protection Layout Guide* (SLVA680) is available for download at www.ti.com.

Typical Application (continued)

9.2.2.2 *Reducing Sensitivity to Ambient Light Modulation*

Ambient light has an additive effect to the LED phase output of the AFE because ambient light occurs on the photodiode in a manner similar to the light originating from the LED. Any artifacts in ambient light can therefore interfere with the extraction of the heart rate from the signal in the LED phase. The purpose of subtracting the ambient phase signal from the LED phase signal is to remove this effect. If the effect of ambient light on the LED and ambient phase outputs is unequal, then subtraction of the ambient phase data from the LED phase data gives only an incomplete cancellation of the ambient light modulation effect. In that case, a periodic pattern in the ambient light can cause spurious tones to appear in the (LED-Ambient) data. The following guidelines can significantly reduce the sensitivity of the AFE to ambient light modulation:

- Follow the timing guidelines listed in Table 7.
- t_1 (the start of the LED to the start of sampling) plays a role in the sensitivity to ambient light modulation. For best performance under high ambient light modulation, keeping t_1 to a value greater than 25 µs is recommended even when operating at low sampling pulse durations.
- The TIA maintains the photodiode bias through negative feedback. If the TIA output saturates, then the photodiode bias is disturbed. The associated transient for the photodiode bias to get restored can increase the sensitivity to ambient light modulation. For example, a saturation of the TIA output during the LED3 phase can lead to the TIA recovery response to span both the LED1 and Ambient1 phases. This scenario can cause the channel response to differ between these two phases, thereby rendering the ambient subtraction through (LED1-Ambient1) to be incomplete. Therefore, the output of every phase is recommended to be prevented from saturating (through periodic signal monitoring and gain adjustment) even if the data from that phase is not being used by the heart rate estimation algorithm.
- If the ambient light changes at a fast rate, the effective ambient signal observed during the LED and ambient phases can be different because of the difference between the sampling instants. This effect can also cause the ambient subtraction to be incomplete. Reducing the spacing between the sampling instants of the LED and ambient can reduce this effect.

Figure 93 is the AFE output in the ambient phase resulting from modulation applied to the ambient light. Figure 94 is the (LED-Ambient) phase data with non-optimal settings and Figure 95 is the (LED-Ambient) phase data with optimal settings.

Figure 93. Ambient Data with Ambient Light Modulation

Figure 94. (LED-Ambient) Data with a Non-Optimal AFE Setting

Product Folder Links: *AFE4404*

Typical Application (continued)

Figure 95. (LED-Ambient) Data with an Optimal AFE Setting
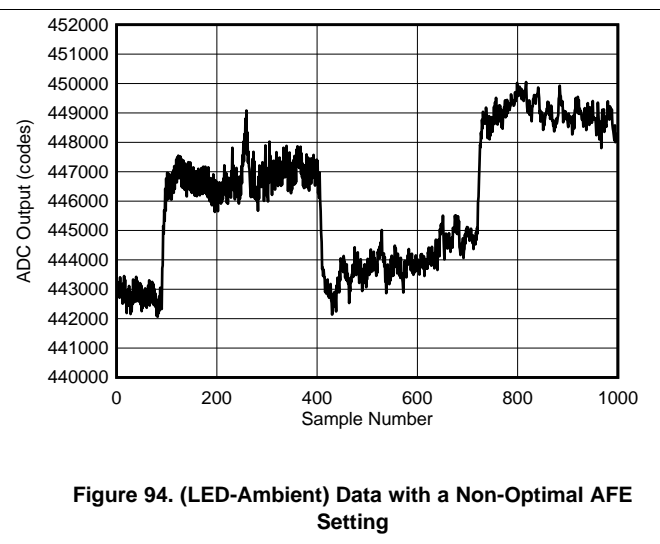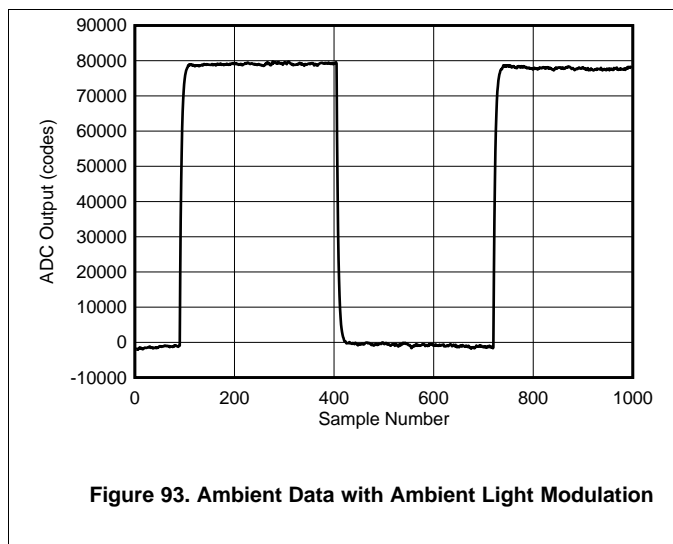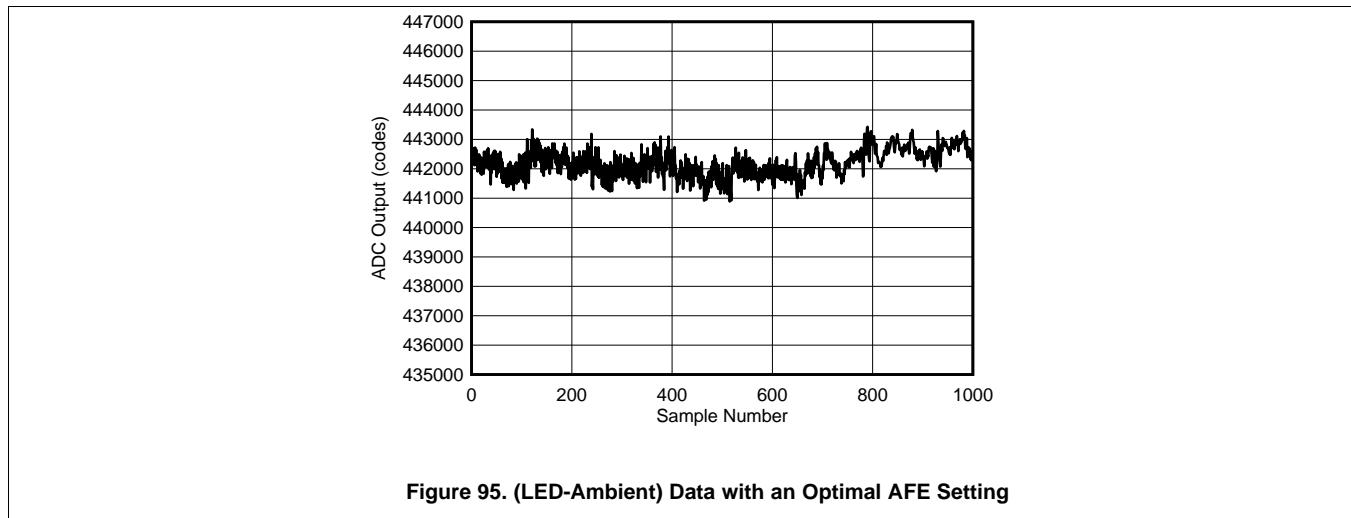
9.2.3 Application Curves

This section outlines the trends described in the *Typical Characteristics* section from an application perspective.

Figure 1 illustrates the receiver current across different external clock frequencies. Each of the curves corresponds to a different CLKDIV_EXTMODE setting that determines the division ratio between the external clock and the internal clock (CLK_INT). The internal clock frequency must be in the range of 4 MHz to 6 MHz for proper operation, and each curve corresponds to a sweep of the external clock frequency that corresponds to an internal clock frequency sweep over the range of 4 MHz to 6 MHz.

Figure 2 illustrates the receiver current across the PRF with the dynamic power-down signal (PDN_CYCLE) enabled during the portion of the period when the receiver does not need to be active. The active period is maintained as 500 μs for each PRF setting and the device is in power-down mode (set by PDN_CYCLE) for the rest of the period. Additionally, the timing margins indicated as t_8 and t_9 in Figure 35 are included before and after the PDN_CYCLE pulse. The fraction of time that the device is in power-down mode over a period increases with reduction in the PRF because the period scales inversely with PRF. This timing is the reason why the curve displays a reduction in the average receiver current with reduction in PRF. The curve corresponding to CLKDIV_PRF = 1 terminates at a lower PRF of approximately 61 Hz, which is determined by the maximum range of the 16-bit timing counter (4 MHz divided by 2^{16}). With the CLKDIV_PRF set to 16, the timer clock is divided by 16. Thus, the lower PRF range can be extended down to a few hertz (the recommended operation is to restrict the range to 10 Hz or higher). For the same PRF (for example 100 Hz), a higher CLKDIV_PRF setting results in a lower power consumption because the timer engine runs on a slower clock and takes less switching current.

The noise plots from Figure 3 to Figure 7 are taken at a PRF of 100 Hz. For this PRF setting, the noise at the output of the AFE is distributed from 0 Hz to 50 Hz. Plots that indicate the noise as over Nyquist bandwidth have integrated noise from 1 Hz to 50 Hz. The plots that indicate the noise as over 20-Hz bandwidth have integrated noise until 20 Hz. These plots are suitable for when additional low-pass filtering is implemented in the MCU to limit the noise bandwidth (in this case, to 20 Hz). This low-pass filtering can improve SNR because the PPG signal has information contained in the frequency band below 10 Hz.

Figure 3 illustrates the input-referred noise current versus sampling duration duty cycle for different voltage levels at the receiver output. The PPG signal has a dc component that can cause the signal at the output of the receiver to be anywhere between ±FS (full-scale). The curves in Figure 3 illustrate a slight increase in the noise around higher dc levels, which results from additional noise sources in the ADC. The input-referred noise current can be visualized as a noise current flowing into one of the input pins (for instance, INP) and flowing out of the other (for example, INM). The noise is computed on the samples that constitute the difference between the LED phase and the ambient phase.

Typical Application (continued)

Figure 4 illustrates the SNR plots corresponding to the same data as Figure 3. The input-referred noise and SNR can be related as follows: the input-referred noise current can be first referred to the receiver output using a factor of 2R$_f$, where R$_f$ is 500 kΩ for this case. This output-referred voltage gives the output noise that can then be referred to the full-scale value of 2 V (note that when the full-scale differential input to the ADC is 2.4 V$_{PP}$, the operating range is 2 V$_{PP}$, which is the valid operating range of the TIA).

Figure 5 plots the input-referred noise current versus sampling duty cycle across different TIA gain settings.

Figure 6 corresponds to the SNR plot of the data in Figure 5. As illustrated in Figure 5, a dynamic range of 100 dB or more can be achieved in the receiver for many of the TIA gain settings. A reduction in SNR for higher TIA gain settings is in line with what is expected from the receiver because a higher TIA gain setting implies a lower signal level at the input of the receiver.

Figure 7 and Figure 8 correspond to the input-referred noise current and corresponding SNR across the sampling duration duty cycle for different settings of the ADC averaging (as set by the NUMAV register setting). An ADC averaging of 1 implies no averaging. As illustrated in these curves, the SNR improves with averaging more samples. This improvement becomes more pronounced at lower TIA gain settings where the ADC noise has a higher affect on the overall receiver noise.

The input-referred current noise current versus sampling duty cycle for different decimation factors is illustrated in Figure 9. As illustrated in Figure 9, a 4X decimation leads to almost a 2X reduction in input-referred noise.

Figure 10 refers to a hypothetical case that is used to illustrate the improvement in the receiver dynamic range when using the offset cancellation DAC. Assume that the dc level of the signal current corresponds to 7.25 µA. Without the offset cancellation DAC, assume operation is with a TIA gain of 25 kΩ, which causes the output of the receiver to be at 362.5 mV. If the offset cancellation DAC is enabled with a subtraction current of 7 µA (the maximum setting), then the signal level at the input of the TIA after the offset cancellation DAC subtraction is 0.25 µA. For this current, a TIA gain setting of 1 MΩ causes the TIA output to be at 500 mV. In effect, by enabling the offset cancellation DAC with the right setting, a higher TIA gain setting is allowed, which ends up reducing the contribution of the ADC noise and thereby reduces the input-referred noise current of the receiver. Note that the benefit from the offset cancellation DAC may not be so dramatic in an actual use case because perfect cancellation of the dc signal may not be achieved from the 0.5-µA resolution of the offset cancellation DAC. Even if achieved, the highest possible TIA gain setting on the residual current may cause receiver saturation with small changes in the dc signal level. For this reason, a safe value for the maximum gain setting when operating with the offset cancellation DAC is 250 kΩ or less. The third curve in Figure 10 illustrates this case.

Figure 11 illustrates the effective response of the switched RC filter at the receiver output. The switched RC filter has a physical RC time constant that corresponds to a bandwidth of approximately 2.5 kHz. However, the effective bandwidth of the filter scales approximately with the sampling duration duty cycle. For a lower duty cycle, the effective filter bandwidth reduces as described from the comparison of a 5% duty cycle with a 25% duty cycle. At even lower duty cycles, the filter can double-up as a noise bandwidth reduction filter that can relax the digital-filtering requirements in the MCU.

Figure 12 illustrates the switched RC filter response for a sampling duty cycle of 1% across different PRF settings.

Figure 13 illustrates the switched RC filter response for a sampling duty cycle of 5% across different PRF settings.

Figure 14 illustrates the LED current value versus the LED current setting code. The mode marked as *50-mA LED Current Mode* corresponds to the default setting of ILED_2X = 0, whereas the mode marked as *100-mA LED Current Mode* corresponds to ILED_2X = 1. The ideal slope of these curves corresponds to 0.793 mA per code for the 50-mA current mode and 1.587 mA per code for the 100-mA current mode. However, a small deviation from these ideal values can exist from device to device, and can be viewed as a gain error in the LED current versus code. This deviation can be larger for the 100-mA current mode, with slight saturation of current especially at the high-current settings.

Product Folder Links: *AFE4404*

Typical Application (continued)

Figure 15 illustrates the LED current as a function of the voltage at the TX pin. The voltage at the TX pin is changed by connecting a load resistor from the TX pin to TX_SUP and changing the voltage of TX_SUP. In the 50-mA current mode, with a 50-mA current setting, the LED current starts to drop when the voltage at the TX pin goes below 0.5 V. In the 100-mA current mode, with a 100-mA current setting, the current starts to drop when the voltage at the TX pin goes below 1 V.

Figure 16 and Figure 17 illustrate the LED current step error as a function of the LED current setting code for the 50-mA and 100-mA current modes. These plots are generated from the data in Figure 14 after removing the gain error component (based on the best-fit curve).

Figure 18 illustrates the power-supply rejection ratio (PSRR) for a tone on the TX_SUP power rail. The frequency of the tone is swept and the magnitude of the same tone at the device output (LED-ambient) is monitored. Note that in cases where the tone frequency is greater than PRF / 2, power is monitored at the aliasing frequency. PSRR is computed as the RMS value of the output tone referred to the RMS value of the tone applied on the supply pin.

Figure 19 illustrates the PSRR for a tone applied on the RX_SUP power rail. PSRR is enhanced because of the presence of an internal LDO that drives the signal chain as well as the differential nature of the signal chain.

Figure 20 illustrates the rejection of a 50-Hz differential input tone. A differential current input with a frequency of 50 Hz is applied on the input pins. The magnitude of the tone at the output of the device (LED minus ambient phase) is converted to an input-referred current and compared with the magnitude of the injected current to estimate the rejection. The rejection is plotted as a function of the separation between the sampling instants of the LED and ambient phases. As illustrated in Figure 20, with reducing separation between the sampling instants, the rejection keeps improving because of an increased correlation of the injected tone between the two phases. A similar rejection is not obtained if only the LED phase data are considered.

Figure 21 illustrates the SNR in dBFS over a 20-Hz bandwidth across sampling duty cycle over multiple operating temperatures ranging from –40°C to 85°C.

Figure 22 illustrates the variation of the internal oscillator frequency over operating temperature on a typical unit.

9.2.3.1 Choosing the Right AFE Settings

The AFE signal chain offers several knobs that can be adjusted to achieve the SNR requirements needed for high-end, clinical, pulse-oximeter applications as well as for the low-power demands of battery-operated, optical, heart-rate monitoring applications. The knobs include TIA gain (R_f), TIA bandwidth, LED current (ILED), and offset cancellation DAC (I_OFFDAC). TI highly recommends running a calibration algorithm at startup and also periodically on the MCU to monitor the dc level at the output of the AFE and adjust the AFE signal chain settings to get close to the target dc level.

In addition to a target dc level, the high and low thresholds can also be determined (for example, 80% and 20% of full-scale), which can cause the algorithm to switch to a different TIA gain or LED current setting when the signal amplitude changes beyond the thresholds.

The optimum gain and LED current depends on the following conditions:

1. The current transfer ratio (CTR) from the LED to the photodiode
2. The perfusion index at the ADC output (the ac to dc ratio of the signal)

For clinical SPO2 applications demanding the highest SNR, where power may not be a primary concern, TI recommends setting the LED and sampling pulse durations to > 200 µs. To simplify system design, keeping the pulse duration fixed across use cases is easiest. Set the LED current to the highest value that can be afforded by the system power budget. Initialize the TIA gain to the lowest gain setting of 10 kΩ and use the initial calibration routine to determine the optimum gain. Set the ADC in averaging mode with the number of averages being the maximum afforded by the choice of pulse repetition period and pulse duration. Eight ADC averages is usually sufficient to obtain good SNR.

For power-critical, battery-operated applications, choose a sampling pulse duration between 50 µs to 100 µs and operate the device at a high TIA gain setting (for example, 1 MΩ). Set the ADC in averaging mode with four to eight averages. Initialize the LED current to the desired lowest setting (of a few milliamps) and use the initial calibration routine to determine the optimum LED current setting up to the highest value allowed by the system power budget.

Typical Application (continued)

For pulse-oximeter applications using red and IR LEDs, the target dc level can be typically set to 50% of positive full-scale.

For HRM applications, the offset cancellation DAC can be additionally used such that the dc offset can be subtracted from the signal, thereby allowing for a larger TIA gain to be applied without saturating the signal.

The calibration routine must be designed in a manner that does not rely on the accuracy of the LED current, TIA gain, and offset cancellation DAC, thus allowing for device-to-device variations. Specifically, the offset cancellation DAC is not trimmed at production and can have a significant device-to-device variation (±20%). If the calibration routine requires an accurate estimate of the offset cancellation DAC, then the PD_DISCONNECT mode can be used to estimate the offset cancellation DAC range on a given unit. The PD_DISCONNECT mode disconnects the photodiode from the TIA inputs. In this mode IPD = 0 and, thus, the effective input current to the TIA comes solely from the offset cancellation DAC (I_{eff} = I_OFFDAC). As a result, the offset cancellation DAC value can be directly estimated from the AFE output code.

When the calibration loop is in the process of converging to the steady state, the device settings can continue to be refreshed to new values. Ideally, a time equal to $t_{CHANNEL}$ is provided for the AFE to settle to any change in signal-chain settings. However, this time can lead to unacceptably large delays in the convergence of the calibration routine. Therefore, during the transient (when the calibration routine is in the transient phase), the wait times can be reduced to as low as $t_{CHANNEL}$ / 10. After the calibration routine converges to the final settings, a wait time of $t_{CHANNEL}$ can then be applied before high-accuracy data are read out from the AFE.

Product Folder Links: *AFE4404*

10   Power Supply Recommendations

The guidelines for power-supply sequencing and device initialization are shown in Figure 96, Figure 97, and Table 79.
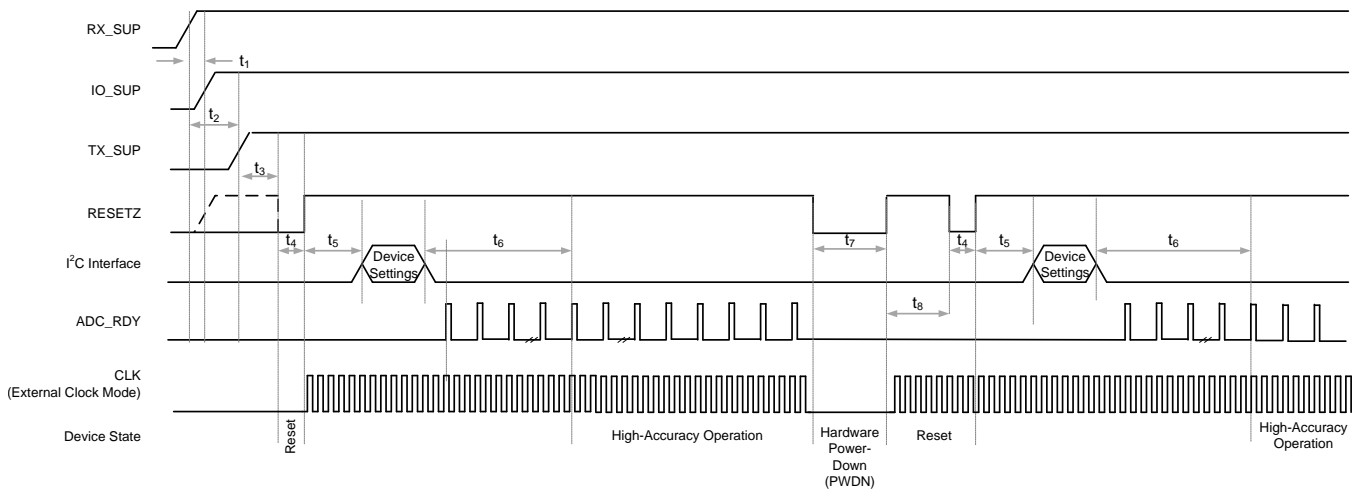
Figure 96. Power-Supply Sequencing, Device Initialization, and Hardware Power-Down Timing
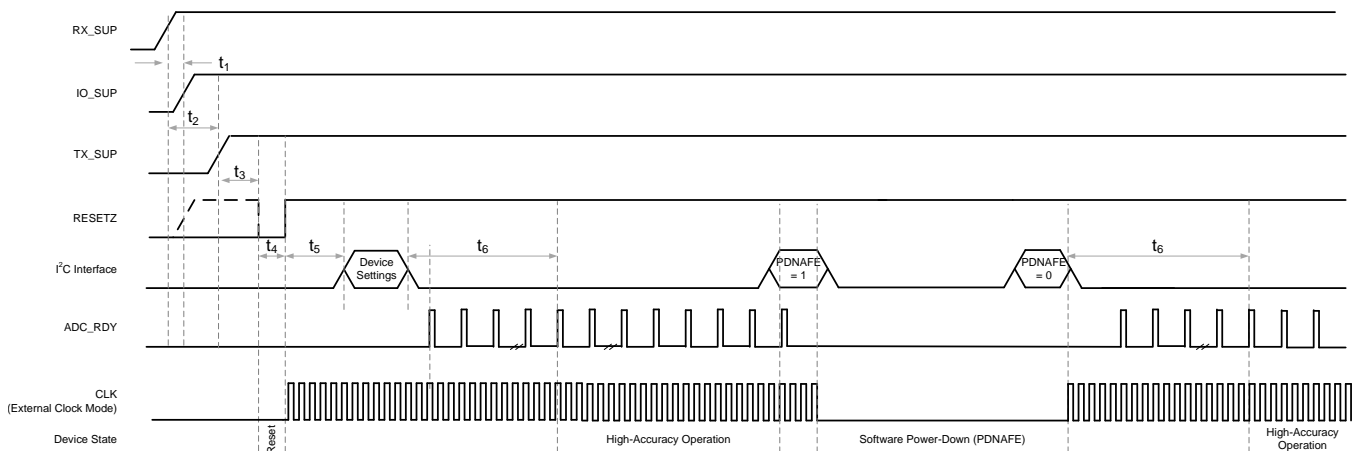
Figure 97. Power-Supply Sequencing, Device Initialization, and Software Power-Down Timing

Table 79. Timing Parameters for Power Supply Sequencing, Device Initialization, and Power-Down Timing

		VALUE
t_1	Time between RX_SUP and IO_SUP ramping up	Ramp up RX_SUP before or at the same time as IO_SUP. Keep t_1 as small as possible (for example,10 ms).
t_2	Time between RX_SUP and TX_SUP ramping up	Keep t_2 as small as possible (for example,10 ms).
t_3	Time between all supplies stabilizing and start of the RESETZ low-going pulse	> 10 ms
t_4	RESETZ pulse duration for the device to get reset	Between 25 µs and 50 µs
t_5	Time between resetting the device and issuing of I^{2}C commands	> 1 ms
t_6	Time between I^{2}C commands and the ADC_RDY pulse that corresponds to valid data	$t_{CHANNEL}$ [(1)](#)
t_7	RESETZ pulse duration for the device to enter PWDN (power-down) mode	> 200 µs
t_8	Time from exiting power-down mode and subsequently resetting the device	> 10 ms

(1)   The $t_{CHANNEL}$ parameter is specified in the *Electrical Characteristics* table.

11 Layout

11.1 Layout Guidelines

Two key layout guidelines are:

1. TX1, TX2, and TX3 are fast-switching lines and must be routed away from sensitive lines (such as the INP, INN inputs).
2. The device can draw high-switching currents from the TX_SUP pin. A decoupling capacitor must be electrically close to the pin.

11.2 Layout Example
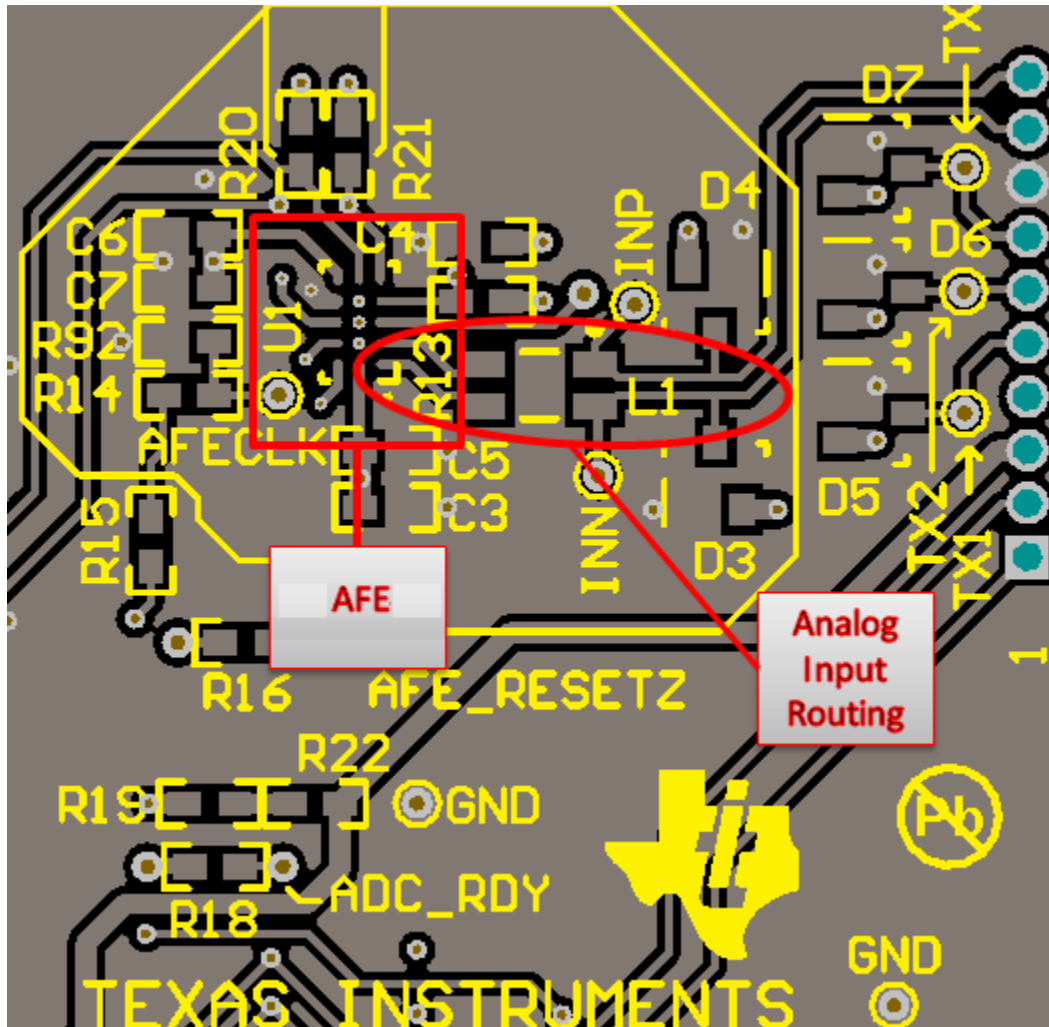
Figure 98. Example Layout

12 Device and Documentation Support

12.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

12.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

TI E2E™ Online Community *TI's Engineer-to-Engineer (E2E) Community.* Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

12.3 Trademarks

E2E is a trademark of Texas Instruments.
Bluetooth is a registered trademark of Bluetooth SIG, Inc.
All other trademarks are the property of their respective owners.

12.4 Electrostatic Discharge Caution

This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

12.5 Glossary

SLYZ022 — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.
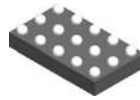
PACKAGE OUTLINE

YZP0015

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY

E = 1.6 mm
D = 2.6 mm

BALL A1 CORNER

0.5 MAX

0.19
0.13

BALL TYP

SEATING PLANE

0.05 C

1 TYP

0.5 TYP

2 TYP

0.5 TYP

SYMM

SYMM

15X Ø 0.25
       0.21

0.015 S | C | A S | B S

4221665/A 09/2014
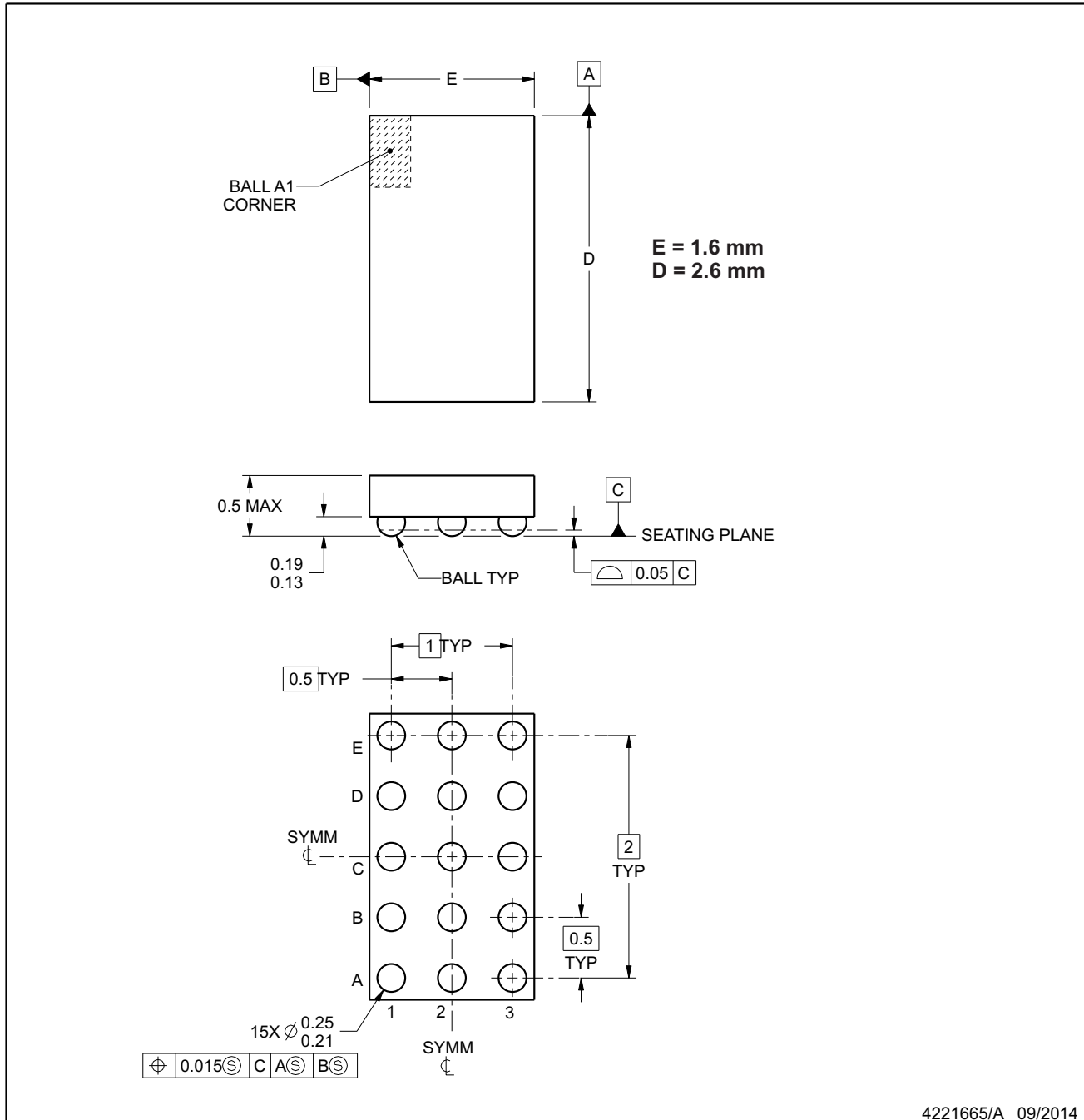
NanoFree Is a trademark of Texas Instruments.

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. NanoFree™ package configuration.

Figure 99. Package Outline

EXAMPLE BOARD LAYOUT

YZP0015

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY

LAND PATTERN EXAMPLE
SCALE:30X

SOLDER MASK DETAILS
NOT TO SCALE

4221665/A 09/2014
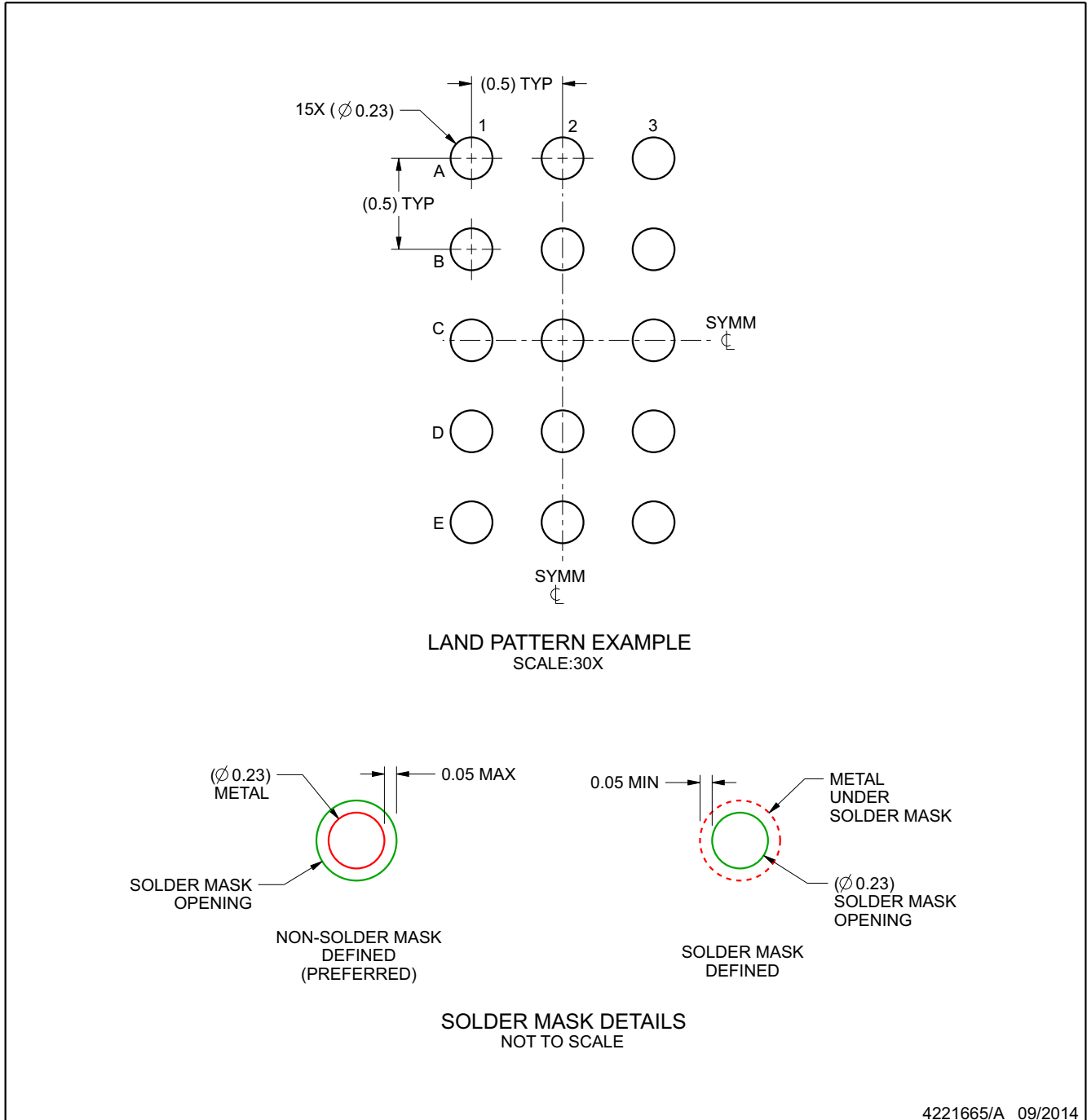
NOTES: (continued)

4. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints.
   For more information, see Texas Instruments literature number SBVA017 (www.ti.com/lit/sbva017).

Figure 100. Example Board Layout

Product Folder Links: *AFE4404*

EXAMPLE STENCIL DESIGN

YZP0015

DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY
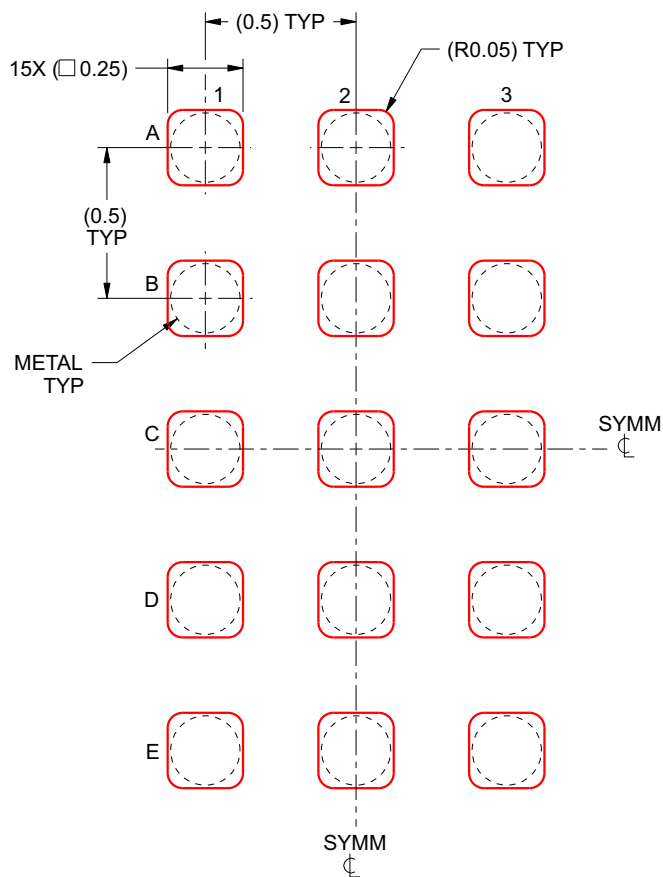
SOLDER PASTE EXAMPLE
BASED ON 0.1 mm THICK STENCIL
SCALE:40X

4221665/A 09/2014

NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.

Figure 101. Example Stencil Design

Product Folder Links: *AFE4404*

![Texas Instruments logo]

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
AFE4404YZPR	ACTIVE	DSBGA	YZP	15	3000	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-20 to 70	AFE4404	Samples
AFE4404YZPT	ACTIVE	DSBGA	YZP	15	250	RoHS & Green	SNAGCU	Level-1-260C-UNLIM	-20 to 70	AFE4404	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION

REEL DIMENSIONS

TAPE DIMENSIONS

A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
AFE4404YZPR	DSBGA	YZP	15	3000	180.0	8.4	1.68	2.68	0.59	4.0	8.0	Q1
AFE4404YZPT	DSBGA	YZP	15	250	180.0	8.4	1.68	2.68	0.59	4.0	8.0	Q1

PACKAGE MATERIALS INFORMATION

TAPE AND REEL BOX DIMENSIONS

*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
AFE4404YZPR	DSBGA	YZP	15	3000	182.0	182.0	20.0
AFE4404YZPT	DSBGA	YZP	15	250	182.0	182.0	20.0

IMPORTANT NOTICE AND DISCLAIMER